



# OPAx316 10-MHz, Low-Power, Low-Noise, RRIO, 1.8-V CMOS Operational Amplifier

## 1 Features

- Unity-Gain Bandwidth: 10 MHz
- Low  $I_Q$ : 400  $\mu$ A/ch
- Wide Supply Range: 1.8 V to 5.5 V
- Low Noise: 11 nV/ $\sqrt{\text{Hz}}$  at 1 kHz
- Low Input Bias Current:  $\pm 5$  pA
- Offset Voltage:  $\pm 0.5$  mV
- Unity-Gain Stable
- Internal RFI/EMI Filter
- Shutdown Version: OPA2316S
- Extended Temperature Range:  $-40^\circ\text{C}$  to  $125^\circ\text{C}$

## 2 Applications

- Battery-Powered Instruments:
  - Consumer, Industrial, Medical
  - Notebooks, Portable Media Players
- Sensor Signal Conditioning
- Automotive Applications
- Barcode Scanners
- Active Filters
- Audio

## 3 Description

The OPA316 family of single, dual, and quad operational amplifiers represents a new generation of general-purpose, low-power operational amplifiers. Featuring rail-to-rail input and output swings, low quiescent current (400  $\mu$ A/ch typical) combined with a wide bandwidth of 10 MHz and very-low noise (11 nV/ $\sqrt{\text{Hz}}$  at 1 kHz) makes this family attractive for a variety of applications that require a good balance between cost and performance. The low input bias current supports those operational amplifiers to be used in applications with M $\Omega$  source impedances.

The robust design of the OPA316 devices provides ease-of-use to the circuit designer—a unity-gain stable, integrated RFI/EMI rejection filter, no phase reversal in overdrive condition, and high electrostatic discharge (ESD) protection (4-kV HBM).

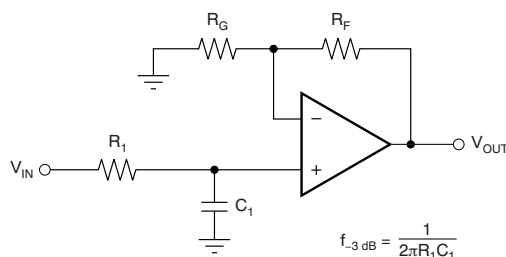
These devices are optimized for low-voltage operation as low as 1.8 V ( $\pm 0.9$  V) and up to 5.5 V ( $\pm 2.75$  V). This latest addition of low-voltage CMOS operational amplifiers, in conjunction with the [OPAx313](#) and [OPAx314](#) provide a family of bandwidth, noise, and power options to meet the needs of a wide variety of applications.

### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE          | BODY SIZE (NOM)          |
|-------------|------------------|--------------------------|
| OPA316      | SC-70 (5)        | 1.25 mm $\times$ 2.00 mm |
|             | SOT-23 (5)       | 1.60 mm $\times$ 2.90 mm |
| OPA2316     | DFN (8)          | 3.00 mm $\times$ 3.00 mm |
|             | MSOP, VSSOP (8)  | 3.00 mm $\times$ 3.00 mm |
|             | SOIC (8)         | 3.91 mm $\times$ 4.90 mm |
| OPA2316S    | MSOP, VSSOP (10) | 3.00 mm $\times$ 3.00 mm |
| OPA4316     | TSSOP (14)       | 4.40 mm $\times$ 5.00 mm |

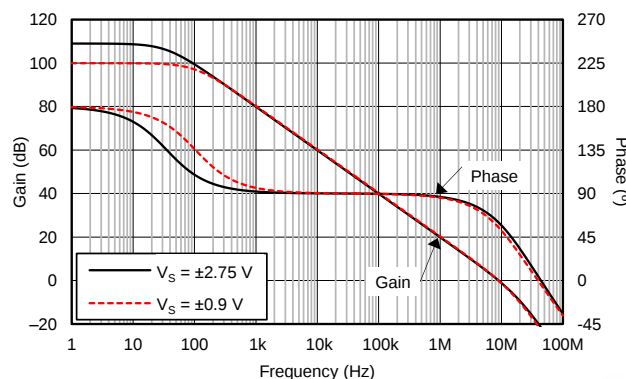
(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Single-Pole, Low-Pass Filter



$$\frac{V_{OUT}}{V_{IN}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1C_1}\right)$$

### Low Supply Current (400 $\mu$ A/ch) for 10-MHz Bandwidth



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision C (October 2014) to Revision D                      | Page |
|---------------------------------------------------------------------------|------|
| • Added <i>Shutdown</i> section to Electrical Characteristics table ..... | 8    |
| • Added <i>Related Documentation</i> section .....                        | 26   |

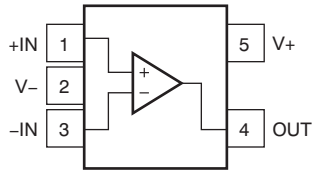
| Changes from Revision B (August 2014) to Revision C                     | Page |
|-------------------------------------------------------------------------|------|
| • Updated devices and packages in <i>Device Information</i> table ..... | 1    |
| • Added thermal information for OPA2316S and OPA4316 .....              | 6    |

| Changes from Revision A (April 2014) to Revision B                        | Page |
|---------------------------------------------------------------------------|------|
| • Added OPA2316 to the <i>Device Information</i> table .....              | 1    |
| • Added thermal information for OPA2316 .....                             | 5    |
| • Added channel separation to <i>Electrical Characteristics</i> .....     | 7    |
| • Added GBP instead of UGB in the <i>Electrical Characteristics</i> ..... | 7    |
| • Added Channel Separation vs Frequency plot .....                        | 15   |

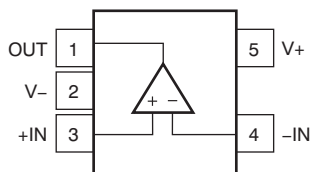
| Changes from Original (April 2014) to Revision A  | Page |
|---------------------------------------------------|------|
| • Changed status from preview to production ..... | 1    |

## 5 Pin Configuration and Functions

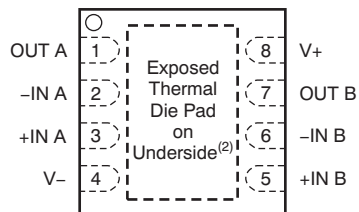
**DCK Package  
SC70-5  
(Top View)**



**DBV Package  
SOT23-5  
(Top View)**



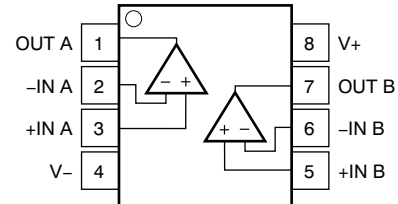
**DRG Package<sup>(1)</sup>  
DFN-8  
(Top View)**



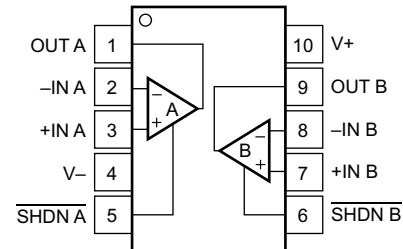
(1) Pitch: 0.5 mm.

(2) Connect thermal pad to V-. Pad size: 2 mm × 1.2 mm.

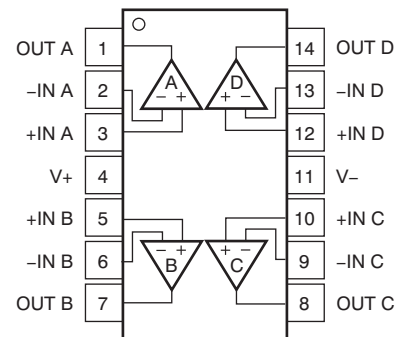
**D, DGK Packages  
SO-8, MSOP-8  
(Top View)**



**DGS Package  
MSOP-10  
(Top View)**



**PW Package  
TSSOP-14  
(Top View)**



## Pin Functions

| NAME   | PIN    |     |             |          |         | DESCRIPTION                                             |
|--------|--------|-----|-------------|----------|---------|---------------------------------------------------------|
|        | OPA316 |     | OPA2316     | OPA2316S | OPA4316 |                                                         |
|        | DBV    | DCK | D, DGK, DRG | DGS      | PW      |                                                         |
| +IN    | 3      | 1   | —           | —        | —       | Noninverting input                                      |
| +IN A  | —      | —   | 3           | 3        | 3       | Noninverting input                                      |
| +IN B  | —      | —   | 5           | 7        | 5       | Noninverting input                                      |
| +IN C  | —      | —   | —           | —        | 10      | Noninverting input                                      |
| +IN D  | —      | —   | —           | —        | 12      | Noninverting input                                      |
| –IN    | 4      | 3   | —           | —        | —       | Inverting input                                         |
| –IN A  | —      | —   | 2           | 2        | 2       | Inverting input                                         |
| –IN B  | —      | —   | 6           | 8        | 6       | Inverting input                                         |
| –IN C  | —      | —   | —           | —        | 9       | Inverting input                                         |
| –IN D  | —      | —   | —           | —        | 13      | Inverting input                                         |
| OUT    | 1      | 4   | —           | —        | —       | Output                                                  |
| OUT A  | —      | —   | 1           | 1        | 1       | Output                                                  |
| OUT B  | —      | —   | 7           | 9        | 7       | Output                                                  |
| OUT C  | —      | —   | —           | —        | 8       | Output                                                  |
| OUT D  | —      | —   | —           | —        | 14      | Output                                                  |
| SHDN A | —      | —   | —           | 5        | —       | Shutdown (logic low), enable (logic high)               |
| SHDN B | —      | —   | —           | 6        | —       | Shutdown (logic low), enable (logic high)               |
| V+     | 5      | 5   | 8           | 10       | 4       | Positive supply                                         |
| V–     | 2      | 2   | 4           | 4        | 11      | Negative supply or ground (for single-supply operation) |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)<sup>(1)</sup>

|                                     |                        |              | MIN               | MAX        | UNIT |
|-------------------------------------|------------------------|--------------|-------------------|------------|------|
| Supply voltage                      |                        |              | 7                 |            | V    |
| Signal input pins                   | Voltage <sup>(2)</sup> | Common-mode  | (V–) – 0.5        | (V+) + 0.5 | V    |
|                                     |                        | Differential | (V+) – (V–) + 0.2 |            | V    |
|                                     | Current <sup>(2)</sup> |              | –10               | 10         | mA   |
| Output short-circuit <sup>(3)</sup> |                        |              | Continuous        |            | mA   |
| T <sub>A</sub>                      | Operating temperature  |              | –55               | 150        | °C   |
| T <sub>J</sub>                      | Junction temperature   |              |                   | 150        | °C   |
| T <sub>stg</sub>                    | Storage temperature    |              | –65               | 150        | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input pins are diode-clamped to the power-supply rails. Current limit input signals that can swing more than 0.5 V beyond the supply rails to 10 mA or less.
- (3) Short-circuit to ground, one amplifier per package.

### 6.2 ESD Ratings

over operating free-air temperature range (unless otherwise noted)

|                    |                         |                                                                                | VALUE | UNIT |
|--------------------|-------------------------|--------------------------------------------------------------------------------|-------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±4000 | V    |
|                    |                         | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1500 |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                               | MIN | NOM | MAX | UNIT |
|-------------------------------|-----|-----|-----|------|
| V <sub>S</sub> Supply voltage | 1.8 |     | 5.5 | V    |
| Specified temperature         | –40 |     | 125 | °C   |

### 6.4 Thermal Information: OPA316

| THERMAL METRIC <sup>(1)</sup> |                                                             | OPA316         |               | UNIT |
|-------------------------------|-------------------------------------------------------------|----------------|---------------|------|
|                               |                                                             | SOT23 (5 PINS) | SC70 (5 PINS) |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance <sup>(2)</sup>       | 221.7          | 263.3         | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance <sup>(3)</sup>     | 144.7          | 75.5          |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance <sup>(4)</sup>         | 49.7           | 51.0          |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter <sup>(5)</sup>   | 26.1           | 1.0           |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter <sup>(6)</sup> | 49.0           | 50.3          |      |
| R <sub>θJC(bot)</sub>         | Junction-to-case(bottom) thermal resistance <sup>(7)</sup>  | N/A            | N/A           |      |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ<sub>JT</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

### 6.5 Thermal Information: OPA2316

| THERMAL METRIC <sup>(1)</sup> |                                                             | OPA2316     |               |              | UNIT |
|-------------------------------|-------------------------------------------------------------|-------------|---------------|--------------|------|
|                               |                                                             | SO (8 PINS) | MSOP (8 PINS) | DFN (8 PINS) |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance <sup>(2)</sup>       | 127.2       | 186.6         | 56.3         | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance <sup>(3)</sup>     | 71.6        | 78.8          | 72.2         |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance <sup>(4)</sup>         | 68.2        | 107.9         | 31.0         |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter <sup>(5)</sup>   | 22.0        | 15.5          | 2.3          |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter <sup>(6)</sup> | 67.6        | 106.3         | 21.2         |      |
| R <sub>θJC(bot)</sub>         | Junction-to-case(bottom) thermal resistance <sup>(7)</sup>  | N/A         | N/A           | 10.9         |      |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ<sub>JT</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

## 6.6 Thermal Information: OPA2316S

| THERMAL METRIC <sup>(1)</sup> |                                                             | OPA2316S       | UNIT |
|-------------------------------|-------------------------------------------------------------|----------------|------|
|                               |                                                             | MSOP (10 PINS) |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance <sup>(2)</sup>       | 189.6          | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance <sup>(3)</sup>     | 73.9           |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance <sup>(4)</sup>         | 110.7          |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter <sup>(5)</sup>   | 13.4           |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter <sup>(6)</sup> | 109.1          |      |
| R <sub>θJC(bot)</sub>         | Junction-to-case(bottom) thermal resistance <sup>(7)</sup>  | N/A            |      |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ<sub>JT</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

## 6.7 Thermal Information: OPA4316

| THERMAL METRIC <sup>(1)</sup> |                                                             | OPA4316         | UNIT |
|-------------------------------|-------------------------------------------------------------|-----------------|------|
|                               |                                                             | TSSOP (14 PINS) |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance <sup>(2)</sup>       | 117.2           | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance <sup>(3)</sup>     | 46.2            |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance <sup>(4)</sup>         | 58.9            |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter <sup>(5)</sup>   | 4.9             |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter <sup>(6)</sup> | 58.3            |      |
| R <sub>θJC(bot)</sub>         | Junction-to-case(bottom) thermal resistance <sup>(7)</sup>  | N/A             |      |

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ<sub>JT</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ<sub>JB</sub>, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining R<sub>θJA</sub>, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

## 6.8 Electrical Characteristics

 $V_S$  (total supply voltage) =  $(V+) - (V-) = 1.8\text{ V to }5.5\text{ V}$ .

At  $T_A = 25^\circ\text{C}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.

| PARAMETER              |                                                  | TEST CONDITIONS                                                                                                                 | MIN        | TYP     | MAX        | UNIT                     |
|------------------------|--------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------|------------|---------|------------|--------------------------|
| OFFSET VOLTAGE         |                                                  |                                                                                                                                 |            |         |            |                          |
| V <sub>OS</sub>        | Input offset voltage                             | V <sub>S</sub> = 5 V                                                                                                            |            | ±0.5    | ±2.5       | mV                       |
|                        |                                                  | V <sub>S</sub> = 5 V, T <sub>A</sub> = −40°C to 125°C                                                                           |            |         | ±3.5       | mV                       |
| dV <sub>OS</sub> /dT   | Drift                                            | V <sub>S</sub> = 5 V, T <sub>A</sub> = −40°C to 125°C                                                                           |            | ±2      | ±10        | μV/°C                    |
| PSRR                   | vs power supply                                  | V <sub>S</sub> = 1.8 V – 5.5 V, V <sub>CM</sub> = (V−)                                                                          |            | ±30     | ±150       | μV/V                     |
|                        |                                                  | V <sub>S</sub> = 1.8 V – 5.5 V, V <sub>CM</sub> = (V−), T <sub>A</sub> = −40°C to 125°C                                         |            |         | ±250       | μV/V                     |
| Channel separation, dc |                                                  | At dc                                                                                                                           |            | 10      |            | μV/V                     |
| INPUT VOLTAGE RANGE    |                                                  |                                                                                                                                 |            |         |            |                          |
| V <sub>CM</sub>        | Common-mode voltage range                        | V <sub>S</sub> = 1.8 V to 2.5 V                                                                                                 | (V−) − 0.2 |         | (V+)       | V                        |
|                        |                                                  | V <sub>S</sub> = 2.5 V to 5.5 V                                                                                                 | (V−) − 0.2 |         | (V+) + 0.2 | V                        |
| CMRR                   | Common-mode rejection ratio                      | V <sub>S</sub> = 1.8 V, (V−) − 0.2 V < V <sub>CM</sub> < (V+) − 1.4 V, T <sub>A</sub> = −40°C to 125°C                          | 70         | 86      |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 5.5 V, (V−) − 0.2 V < V <sub>CM</sub> < (V+) − 1.4 V, T <sub>A</sub> = −40°C to 125°C                          | 76         | 90      |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 1.8 V, V <sub>CM</sub> = −0.2 V to 1.8 V, T <sub>A</sub> = −40°C to 125°C                                      | 57         | 72      |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 5.5 V, V <sub>CM</sub> = −0.2 V to 5.7 V, T <sub>A</sub> = −40°C to 125°C                                      | 65         | 80      |            | dB                       |
| INPUT BIAS CURRENT     |                                                  |                                                                                                                                 |            |         |            |                          |
| I <sub>B</sub>         | Input bias current                               |                                                                                                                                 |            | ±5      | ±15        | pA                       |
|                        |                                                  | T <sub>A</sub> = −40°C to 125°C                                                                                                 |            |         | ±15        | nA                       |
| I <sub>OS</sub>        | Input offset current                             |                                                                                                                                 |            | ±2      | ±15        | pA                       |
|                        |                                                  | T <sub>A</sub> = −40°C to 125°C                                                                                                 |            |         | ±8         | nA                       |
| NOISE                  |                                                  |                                                                                                                                 |            |         |            |                          |
| E <sub>n</sub>         | Input voltage noise (peak-to-peak)               | V <sub>S</sub> = 5 V, f = 0.1 Hz to 10 Hz                                                                                       |            | 3       |            | μV <sub>PP</sub>         |
| e <sub>n</sub>         | Input voltage noise density                      | V <sub>S</sub> = 5 V, f = 1 kHz                                                                                                 |            | 11      |            | nV/√Hz                   |
| i <sub>n</sub>         | Input current noise density                      | f = 1 kHz                                                                                                                       |            | 1.3     |            | fA/√Hz                   |
| INPUT IMPEDANCE        |                                                  |                                                                                                                                 |            |         |            |                          |
| Z <sub>ID</sub>        | Differential                                     |                                                                                                                                 |            | 2    2  |            | 10 <sup>16</sup> Ω    pF |
| Z <sub>IC</sub>        | Common-mode                                      |                                                                                                                                 |            | 2    4  |            | 10 <sup>11</sup> Ω    pF |
| OPEN-LOOP GAIN         |                                                  |                                                                                                                                 |            |         |            |                          |
| A <sub>OL</sub>        | Open-loop voltage gain                           | V <sub>S</sub> = 1.8 V, (V−) + 0.04 V < V <sub>O</sub> < (V+) − 0.04 V, R <sub>L</sub> = 10 kΩ                                  | 94         | 100     |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 5.5 V, (V−) + 0.05 V < V <sub>O</sub> < (V+) − 0.05 V, R <sub>L</sub> = 10 kΩ                                  | 104        | 110     |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 1.8 V, (V−) + 0.1 V < V <sub>O</sub> < (V+) − 0.1 V, R <sub>L</sub> = 2 kΩ                                     | 90         | 96      |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 5.5 V, (V−) + 0.15 V < V <sub>O</sub> < (V+) − 0.15 V, R <sub>L</sub> = 2 kΩ                                   | 100        | 106     |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 5.5 V, (V−) + 0.05 V < V <sub>O</sub> < (V+) − 0.05 V, R <sub>L</sub> = 10 kΩ, T <sub>A</sub> = −40°C to 125°C | 86         |         |            | dB                       |
|                        |                                                  | V <sub>S</sub> = 5.5 V, (V−) + 0.15 V < V <sub>O</sub> < (V+) − 0.15 V, R <sub>L</sub> = 2 kΩ, T <sub>A</sub> = −40°C to 125°C  | 84         |         |            | dB                       |
| FREQUENCY RESPONSE     |                                                  |                                                                                                                                 |            |         |            |                          |
| GBP                    | Gain bandwidth product                           | V <sub>S</sub> = 5 V, G = +1                                                                                                    |            | 10      |            | MHz                      |
| Φ <sub>m</sub>         | Phase margin                                     | V <sub>S</sub> = 5 V, G = +1                                                                                                    |            | 60      |            | Degrees                  |
| SR                     | Slew rate                                        | V <sub>S</sub> = 5 V, G = +1                                                                                                    |            | 6       |            | V/μs                     |
| t <sub>S</sub>         | Settling time                                    | To 0.1%, V <sub>S</sub> = 5 V, 2-V step , G = +1, C <sub>L</sub> = 100 pF                                                       |            | 1       |            | μs                       |
|                        |                                                  | To 0.01%, V <sub>S</sub> = 5 V, 2-V step , G = +1, C <sub>L</sub> = 100 pF                                                      |            | 1.66    |            | μs                       |
| t <sub>OR</sub>        | Overload recovery time                           | V <sub>S</sub> = 5 V, V <sub>IN</sub> × gain = V <sub>S</sub>                                                                   |            | 0.3     |            | μs                       |
| THD + N                | Total harmonic distortion + noise <sup>(1)</sup> | V <sub>S</sub> = 5 V, V <sub>O</sub> = 0.5 V <sub>RMS</sub> , G = +1, f = 1 kHz                                                 |            | 0.0008% |            |                          |

(1) Third-order filter; bandwidth = 80 kHz at -3 dB.

## Electrical Characteristics (continued)

 $V_S$  (total supply voltage) =  $(V+) - (V-) = 1.8\text{ V to }5.5\text{ V}$ .

At  $T_A = 25^\circ\text{C}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.

| PARAMETER                                                 |                                                           | TEST CONDITIONS                                                                     | MIN        | TYP  | MAX        | UNIT |
|-----------------------------------------------------------|-----------------------------------------------------------|-------------------------------------------------------------------------------------|------------|------|------------|------|
| OUTPUT                                                    |                                                           |                                                                                     |            |      |            |      |
| V <sub>O</sub>                                            | Voltage output swing from supply rails                    | V <sub>S</sub> = 1.8 V, R <sub>L</sub> = 10 kΩ, T <sub>A</sub> = −40°C to 125°C     |            |      | 15         | mV   |
|                                                           |                                                           | V <sub>S</sub> = 5.5 V, R <sub>L</sub> = 10 kΩ, T <sub>A</sub> = −40°C to 125°C     |            |      | 30         | mV   |
|                                                           |                                                           | V <sub>S</sub> = 1.8 V, R <sub>L</sub> = 2 kΩ, T <sub>A</sub> = −40°C to 125°C      |            |      | 60         | mV   |
|                                                           |                                                           | V <sub>S</sub> = 5.5 V, R <sub>L</sub> = 2 kΩ, T <sub>A</sub> = −40°C to 125°C      |            |      | 120        | mV   |
| I <sub>SC</sub>                                           | Short-circuit current                                     | V <sub>S</sub> = 5 V                                                                |            | ±50  |            | mA   |
| Z <sub>O</sub>                                            | Open-loop output impedance                                | V <sub>S</sub> = 5 V, f = 10 MHz                                                    |            | 250  |            | Ω    |
| POWER SUPPLY                                              |                                                           |                                                                                     |            |      |            |      |
| V <sub>S</sub>                                            | Specified voltage range                                   |                                                                                     | 1.8        |      | 5.5        | V    |
| I <sub>Q</sub>                                            | Quiescent current per amplifier                           | V <sub>S</sub> = 5 V, I <sub>O</sub> = 0 mA, T <sub>A</sub> = −40°C to 125°C        |            | 400  | 500        | μA   |
|                                                           | Power-on time                                             | V <sub>S</sub> = 0 V to 5.5 V                                                       |            | 200  |            | μs   |
| SHUTDOWN (V <sub>S</sub> = 1.8 V to 5.5 V) <sup>(2)</sup> |                                                           |                                                                                     |            |      |            |      |
| I <sub>QSD</sub>                                          | Quiescent current, per device                             | All amplifiers disabled, $\overline{\text{SHDN}}$ = V <sub>S−</sub>                 |            | 0.01 | 1          | μA   |
|                                                           |                                                           | One amplifier disabled (OPA2316S)                                                   |            | 345  |            | μA   |
| V <sub>IH</sub>                                           | High voltage (enabled)                                    | Amplifier enabled                                                                   | (V+) − 0.5 |      |            | V    |
| V <sub>IL</sub>                                           | Low voltage (disabled)                                    | Amplifier disabled                                                                  |            |      | (V−) + 0.2 | V    |
| t <sub>ON</sub>                                           | Amplifier enable time <sup>(3)</sup>                      | Full shutdown, G = 1, V <sub>OUT</sub> = 0.9 × V <sub>S</sub> / 2 <sup>(4)</sup>    |            | 13   |            | μs   |
|                                                           |                                                           | Partial shutdown, G = 1, V <sub>OUT</sub> = 0.9 × V <sub>S</sub> / 2 <sup>(4)</sup> |            | 10   |            | μs   |
| t <sub>OFF</sub>                                          | Amplifier disable time <sup>(3)</sup>                     | G = 1, V <sub>OUT</sub> = 0.1 × V <sub>S</sub> / 2                                  |            | 5    |            | μs   |
|                                                           | $\overline{\text{SHDN}}$ pin input bias current (per pin) | V <sub>IH</sub> = 5.0 V                                                             |            | 3.5  |            | pA   |
|                                                           |                                                           | V <sub>IL</sub> = 0 V                                                               |            | 2.5  |            | pA   |
| TEMPERATURE                                               |                                                           |                                                                                     |            |      |            |      |
|                                                           | Specified range                                           |                                                                                     | −40        |      | 125        | °C   |
| T <sub>A</sub>                                            | Operating range                                           |                                                                                     | −55        |      | 150        | °C   |
| T <sub>stg</sub>                                          | Storage range                                             |                                                                                     | −65        |      | 150        | °C   |

(2) Ensured by design and characterization; not production tested.

(3) Enable time ( $t_{ON}$ ) and disable time ( $t_{OFF}$ ) are defined as the time interval between the 50% point of the signal applied to the  $\overline{\text{SHDN}}$  pin and the point at which the output voltage reaches the 10% (disable) or 90% (enable) level.

(4) Full shutdown refers to the dual OPA2316S having both channels A and B disabled ( $\overline{\text{SHDN}}_A = \overline{\text{SHDN}}_B = V_{S-}$ ). For partial shutdown, only one  $\overline{\text{SHDN}}$  pin is exercised; in partial mode, the internal biasing and oscillator remain operational and the enable time is shorter.

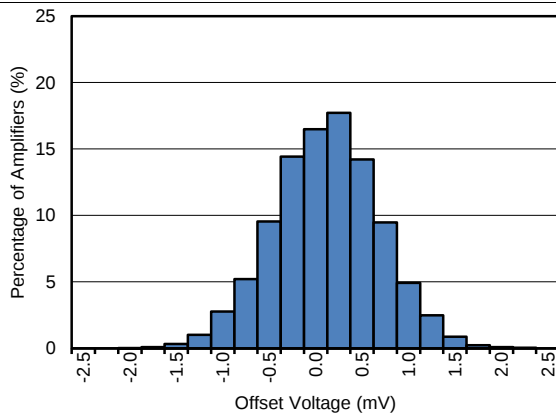
## 6.9 Typical Characteristics: Table of Graphs

**Table 1. Characteristic Performance Measurements**

| TITLE                                                                                                | FIGURE                                                |
|------------------------------------------------------------------------------------------------------|-------------------------------------------------------|
| Offset Voltage Production Distribution                                                               | <a href="#">Figure 1</a>                              |
| Offset Voltage Drift Distribution                                                                    | <a href="#">Figure 2</a>                              |
| Offset Voltage vs Temperature                                                                        | <a href="#">Figure 3</a>                              |
| Offset Voltage vs Common-Mode Voltage                                                                | <a href="#">Figure 4</a>                              |
| Offset Voltage vs Power Supply                                                                       | <a href="#">Figure 5</a>                              |
| Open-Loop Gain and Phase vs Frequency                                                                | <a href="#">Figure 6</a>                              |
| Open-Loop Gain vs Temperature                                                                        | <a href="#">Figure 7</a> , <a href="#">Figure 8</a>   |
| Closed-Loop Gain vs Frequency                                                                        | <a href="#">Figure 9</a>                              |
| Input Bias and Offset Current vs Temperature                                                         | <a href="#">Figure 10</a>                             |
| Output Voltage Swing vs Output Current                                                               | <a href="#">Figure 11</a>                             |
| CMRR and PSRR vs Frequency (Referred to Input)                                                       | <a href="#">Figure 12</a>                             |
| CMRR vs Temperature                                                                                  | <a href="#">Figure 13</a> , <a href="#">Figure 14</a> |
| PSRR vs Temperature                                                                                  | <a href="#">Figure 15</a>                             |
| 0.1-Hz to 10-Hz Input Voltage Noise                                                                  | <a href="#">Figure 16</a>                             |
| Input Voltage Noise Spectral Density vs Frequency                                                    | <a href="#">Figure 17</a>                             |
| Input Voltage Noise vs Common-Mode Voltage                                                           | <a href="#">Figure 18</a>                             |
| THD + N vs Frequency                                                                                 | <a href="#">Figure 19</a>                             |
| THD + N vs Amplitude                                                                                 | <a href="#">Figure 20</a>                             |
| Quiescent Current vs Supply Voltage                                                                  | <a href="#">Figure 21</a>                             |
| Quiescent Current vs Temperature                                                                     | <a href="#">Figure 22</a>                             |
| Open-Loop Output Impedance vs Frequency                                                              | <a href="#">Figure 23</a>                             |
| Small-Signal Overshoot vs Load Capacitance                                                           | <a href="#">Figure 24</a> , <a href="#">Figure 25</a> |
| No Phase Reversal                                                                                    | <a href="#">Figure 26</a>                             |
| Positive Overload Recovery                                                                           | <a href="#">Figure 27</a>                             |
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| Small-Signal Step Response                                                                           | <a href="#">Figure 29</a>                             |
| Large-Signal Step Response                                                                           | <a href="#">Figure 30</a>                             |
| Large-Signal Settling Time                                                                           | <a href="#">Figure 31</a> , <a href="#">Figure 32</a> |
| Short-Circuit Current vs Temperature                                                                 | <a href="#">Figure 33</a>                             |
| Maximum Output Voltage vs Frequency and Supply Voltage                                               | <a href="#">Figure 34</a>                             |
| Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR IN+) vs Frequency | <a href="#">Figure 35</a>                             |
| Channel Separation vs Frequency                                                                      | <a href="#">Figure 36</a>                             |

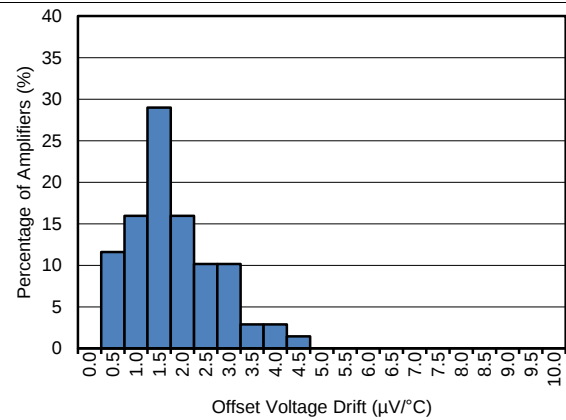
## 6.10 Typical Characteristics

At  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.



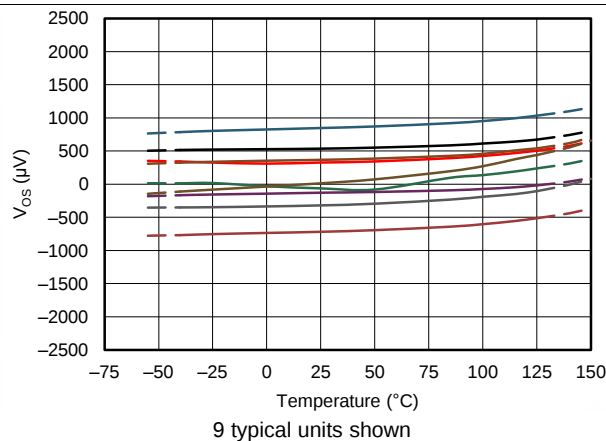
Distribution taken from 12551 amplifiers

Figure 1. Offset Voltage Production Distribution



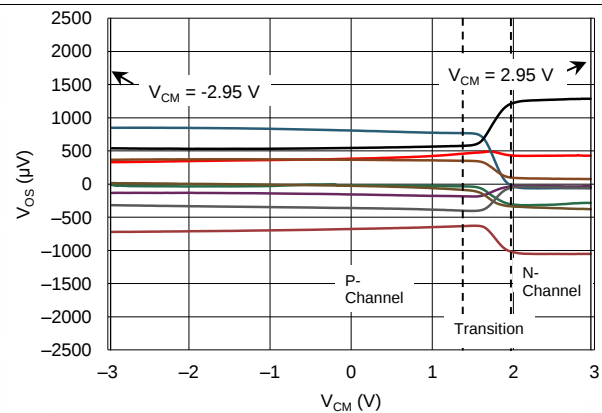
$T_A = -40^\circ\text{C}$  to  $125^\circ\text{C}$ , Distribution taken from 70 amplifiers

Figure 2. Offset Voltage Drift Distribution



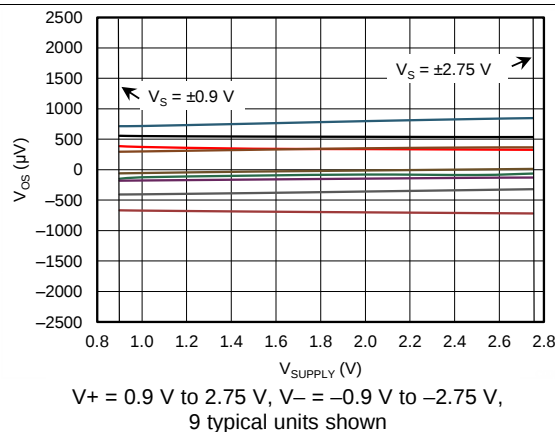
9 typical units shown

Figure 3. Offset Voltage vs Temperature



$V_+ = 2.75\text{ V}$ ,  $V_- = -2.75\text{ V}$ , 9 typical units shown

Figure 4. Offset Voltage vs Common-Mode Voltage



$V_+ = 0.9\text{ V}$  to  $2.75\text{ V}$ ,  $V_- = -0.9\text{ V}$  to  $-2.75\text{ V}$ , 9 typical units shown

Figure 5. Offset Voltage vs Power Supply

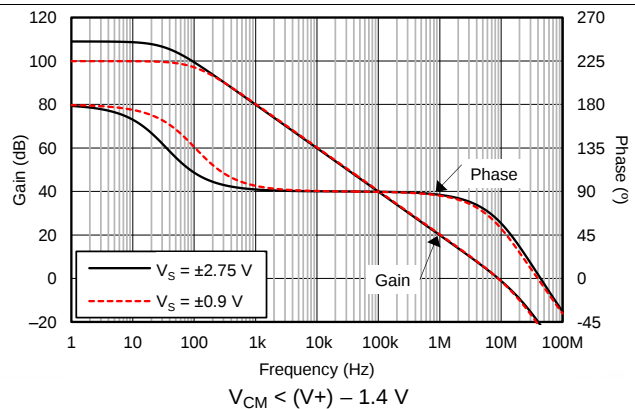
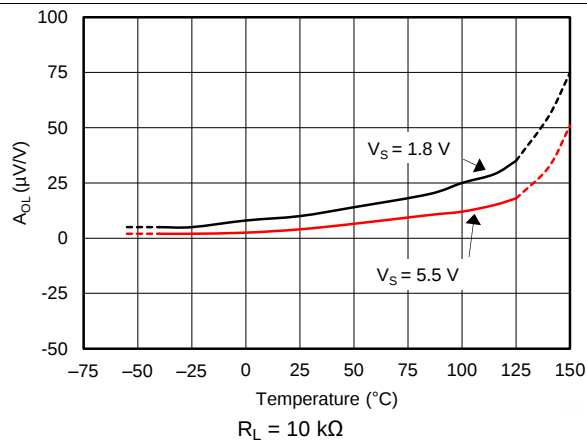


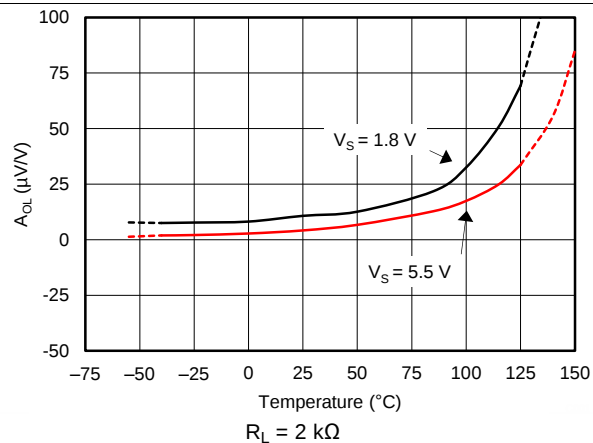
Figure 6. Open-Loop Gain and Phase vs Frequency

## Typical Characteristics (continued)

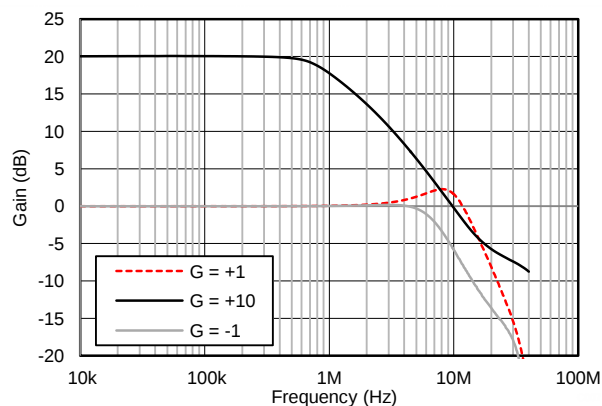
At  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.



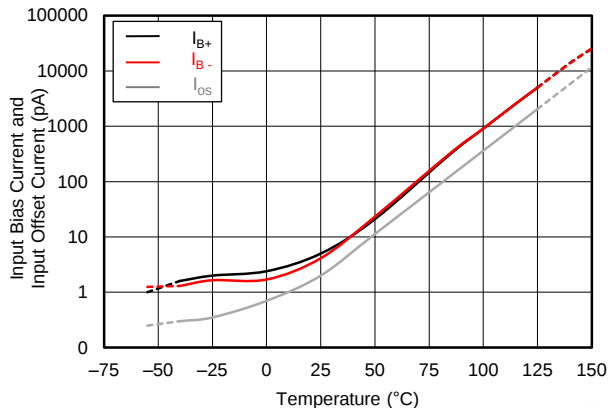
**Figure 7. Open-Loop Gain vs Temperature**



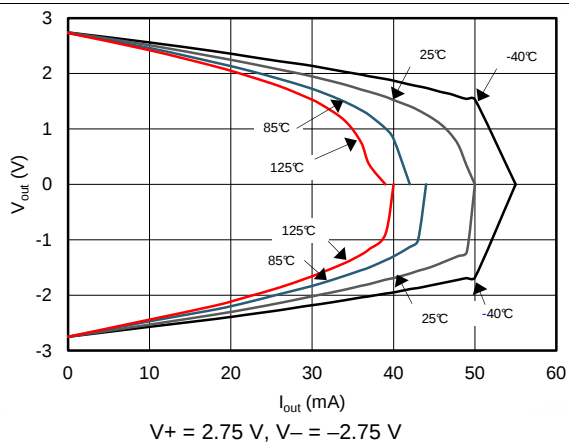
**Figure 8. Open-Loop Gain vs Temperature**



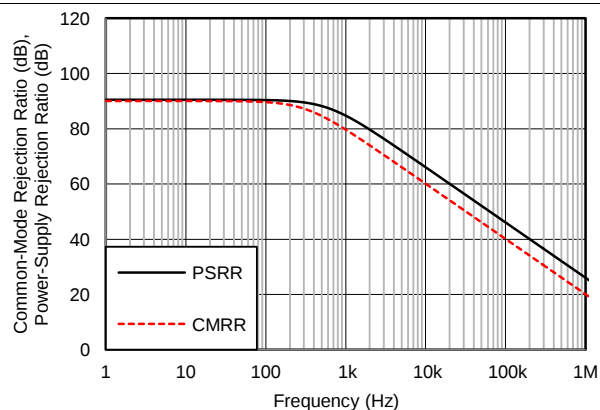
**Figure 9. Closed-Loop Gain vs Frequency**



**Figure 10. Input Bias and Offset Current vs Temperature**



**Figure 11. Output Voltage Swing vs Output Current**



**Figure 12. CMRR and PSRR vs Frequency (Referred to Input)**

## Typical Characteristics (continued)

At  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.

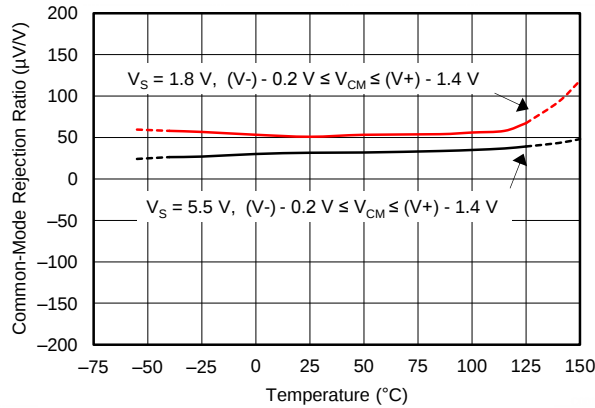


Figure 13. CMRR vs Temperature (Narrow Range)

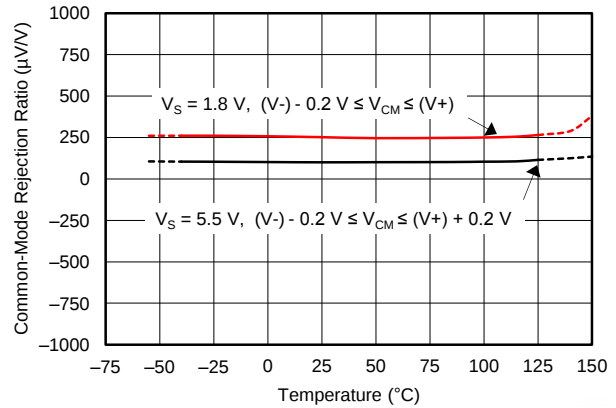


Figure 14. CMRR vs Temperature (Wide Range)

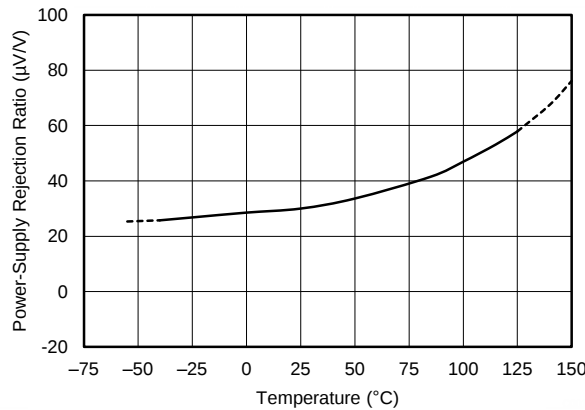


Figure 15. PSRR vs Temperature

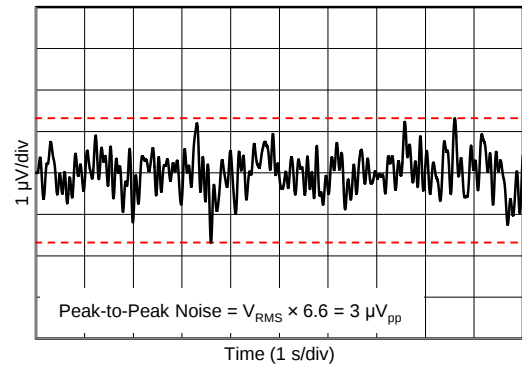


Figure 16. 0.1-Hz to 10-Hz Input Voltage Noise

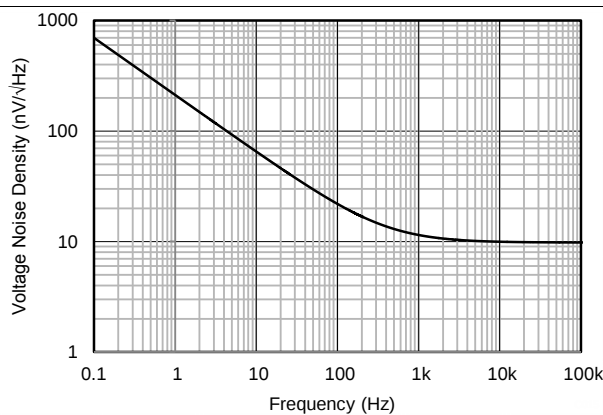


Figure 17. Input Voltage Noise Spectral Density vs Frequency

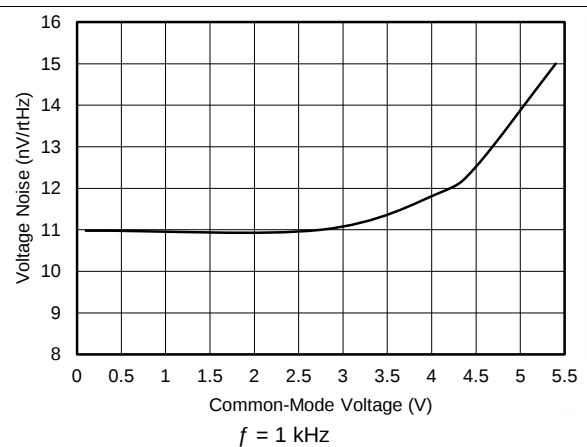
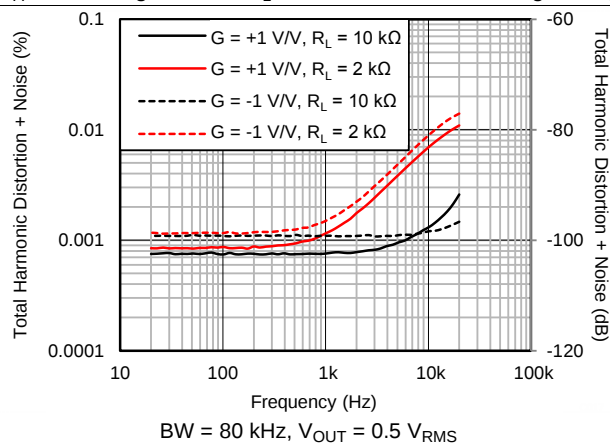


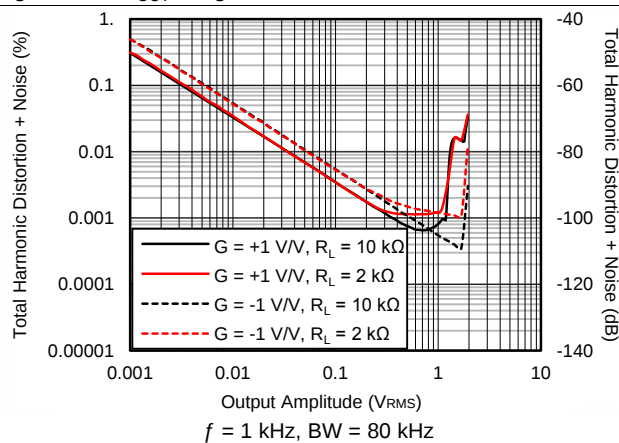
Figure 18. Input Voltage Noise vs Common-Mode Voltage

## Typical Characteristics (continued)

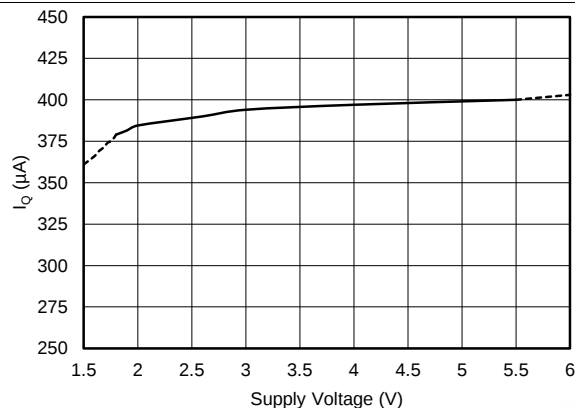
At  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.



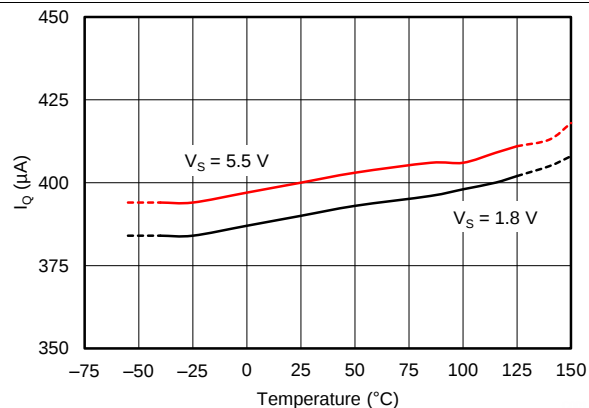
**Figure 19. THD + N vs Frequency**



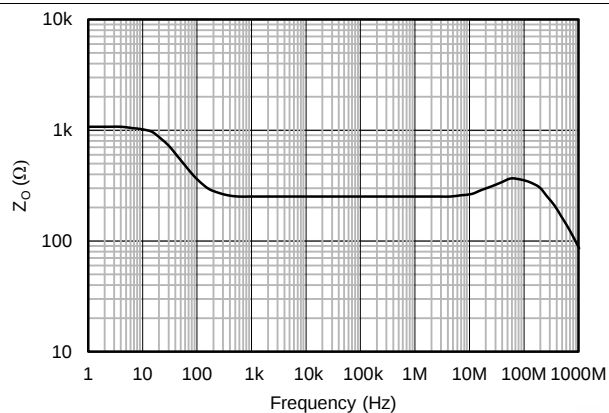
**Figure 20. THD + N vs Amplitude**



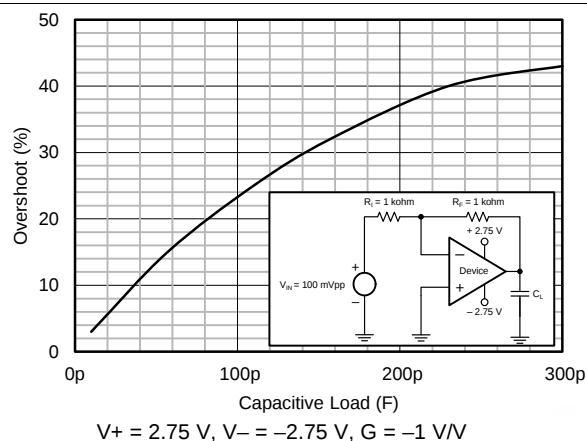
**Figure 21. Quiescent Current vs Supply Voltage**



**Figure 22. Quiescent Current vs Temperature**



**Figure 23. Open-Loop Output Impedance vs Frequency**



**Figure 24. Small-Signal Overshoot vs Load Capacitance**

## Typical Characteristics (continued)

At  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.

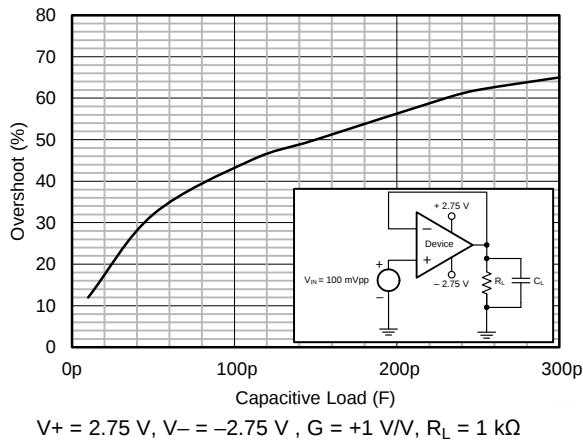


Figure 25. Small-Signal Overshoot vs Load Capacitance

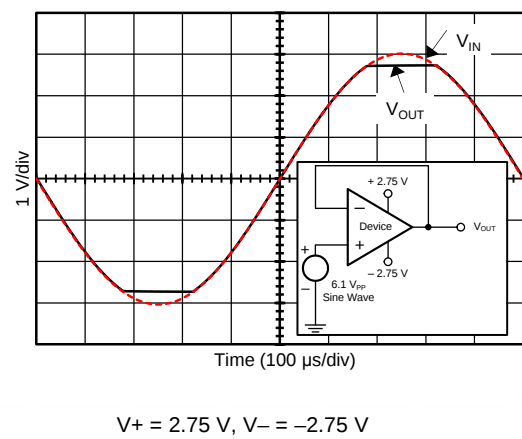


Figure 26. No Phase Reversal

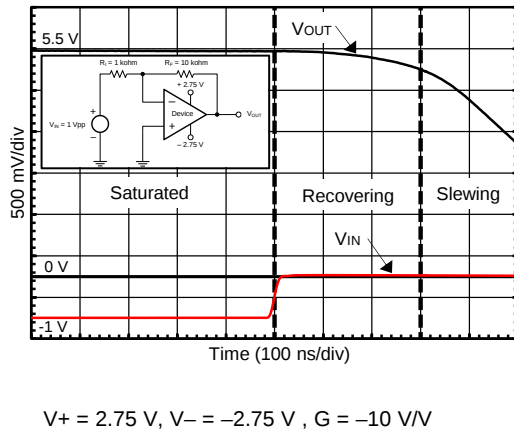


Figure 27. Positive Overload Recovery

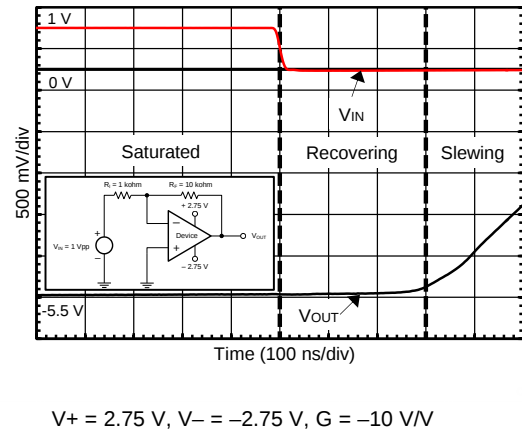


Figure 28. Negative Overload Recovery

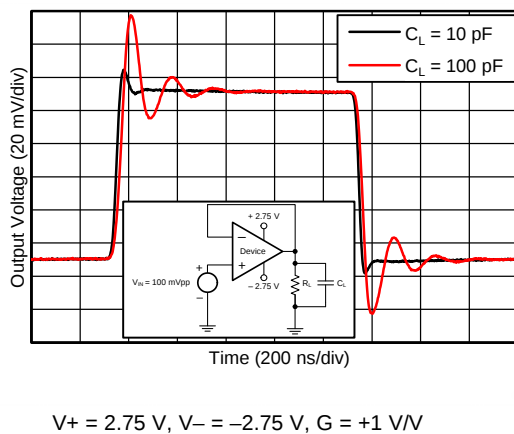


Figure 29. Small-Signal Step Response

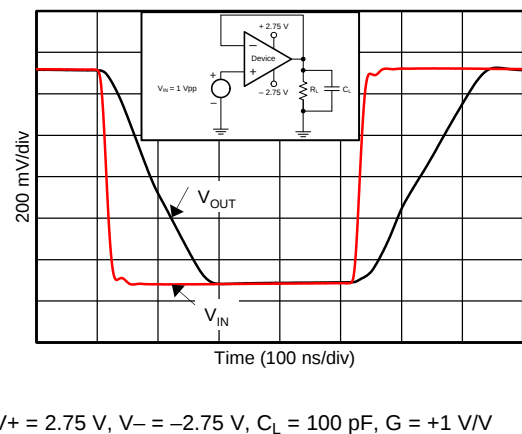
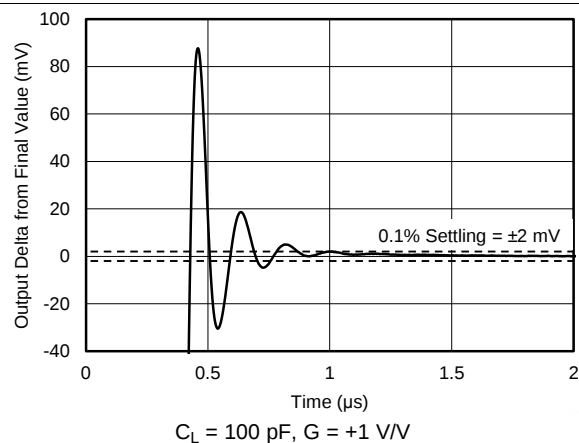


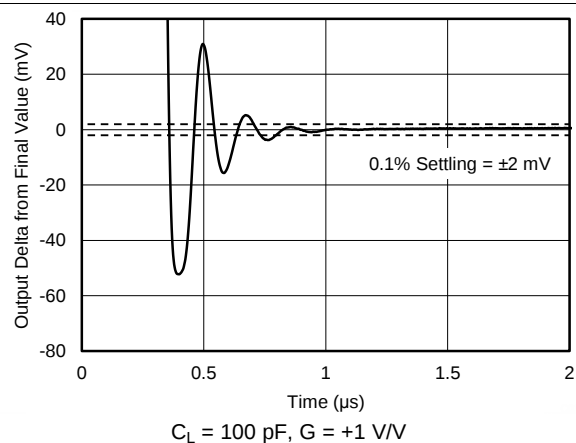
Figure 30. Large-Signal Step Response

## Typical Characteristics (continued)

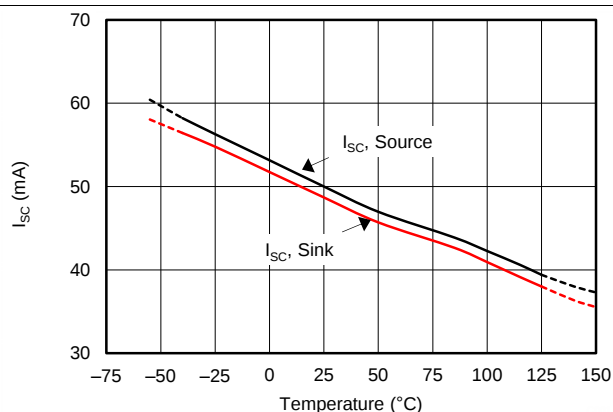
At  $T_A = 25^\circ\text{C}$ ,  $V_S = 5.5\text{ V}$ ,  $R_L = 10\text{ k}\Omega$  connected to  $V_S / 2$ ,  $V_{CM} = V_S / 2$ , and  $V_{OUT} = V_S / 2$ , unless otherwise noted.



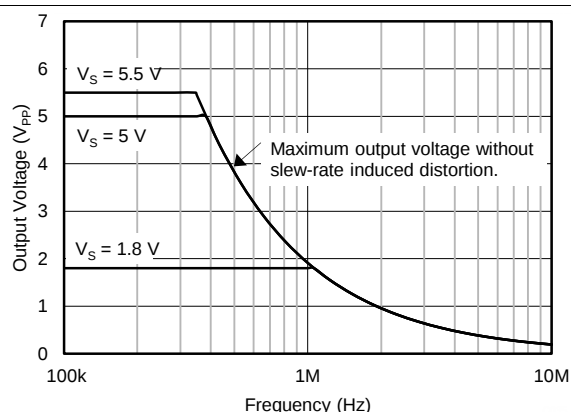
**Figure 31. Positive Large-Signal Settling Time**



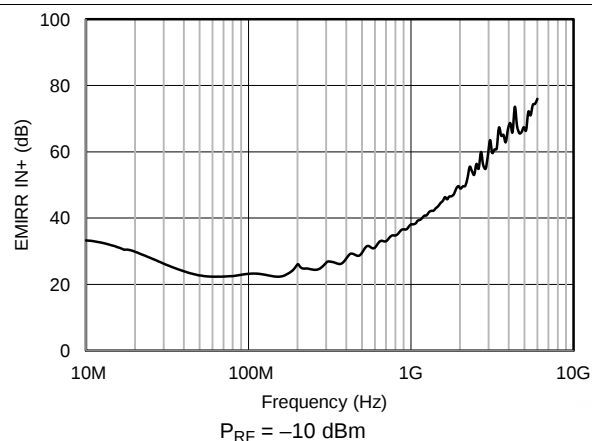
**Figure 32. Negative Large-Signal Settling Time**



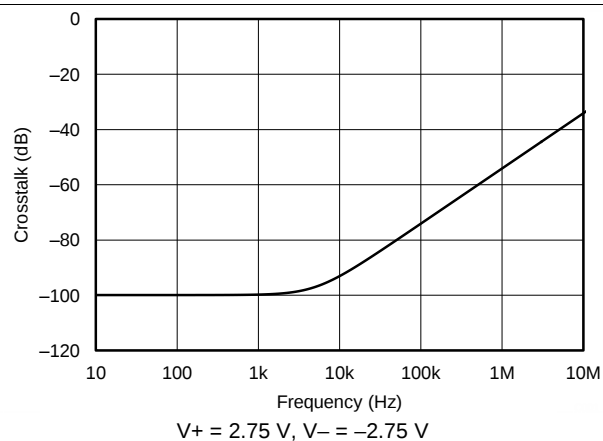
**Figure 33. Short-Circuit Current vs Temperature**



**Figure 34. Maximum Output Voltage vs Frequency and Supply Voltage**



**Figure 35. Electromagnetic Interference Rejection Ratio Referred to Noninverting Input (EMIRR IN+) vs Frequency**



**Figure 36. Channel Separation vs Frequency**

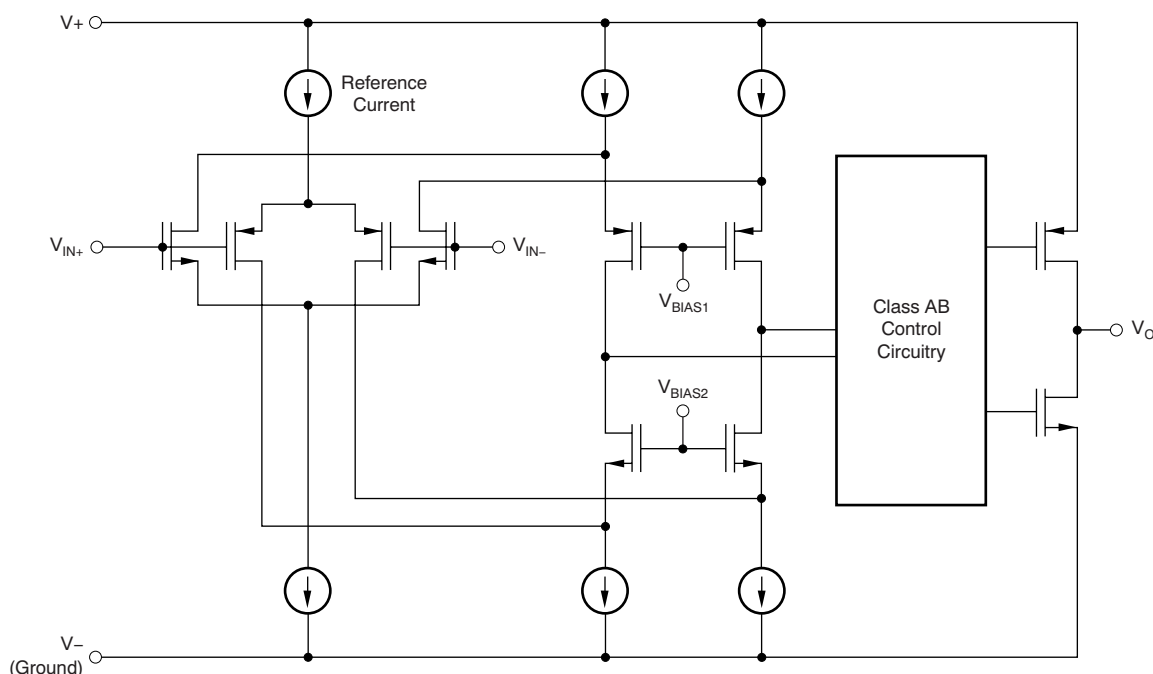
## 7 Detailed Description

### 7.1 Overview

The OPA316 is a family of low-power, rail-to-rail input and output operational amplifiers. These devices operate from 1.8 V to 5.5 V, are unity-gain stable, and are suitable for a wide range of general-purpose applications. The class AB output stage is capable of driving  $\leq 10\text{-k}\Omega$  loads connected to any point between  $V_+$  and ground. The input common-mode voltage range includes both rails and allows the OPA316 series to be used in virtually any single-supply application. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications, and makes them ideal for driving sampling analog-to-digital converters (ADCs).

The OPA316 features 10-MHz bandwidth and 6-V/ $\mu\text{s}$  slew rate with only 400- $\mu\text{A}$  supply current per channel, providing good ac performance at very-low power consumption. DC applications are also well served with a very-low input noise voltage of 11 nV/ $\sqrt{\text{Hz}}$  at 1 kHz, low input bias current (5 pA), and an input offset voltage of 0.5 mV (typical).

### 7.2 Functional Block Diagram



### 7.3 Feature Description

#### 7.3.1 Operating Voltage

The OPA316 series operational amplifiers are fully specified and ensured for operation from 1.8 V to 5.5 V. In addition, many specifications apply from  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . Parameters that vary significantly with operating voltages or temperature are illustrated in the [Typical Characteristics](#) graphs.

#### 7.3.2 Rail-to-Rail Input

The input common-mode voltage range of the OPA316 series extends 200 mV beyond the supply rails for supply voltages greater than 2.5 V. This performance is achieved with a complementary input stage: an N-channel input differential pair in parallel with a P-channel differential pair, as shown in the [Functional Block Diagram](#) section. The N-channel pair is active for input voltages close to the positive rail, typically  $(V_+) - 1.4\text{ V}$  to 200 mV above the positive supply, whereas the P-channel pair is active for inputs from 200 mV below the negative supply to

## Feature Description (continued)

approximately  $(V+) - 1.4$  V. There is a small transition region, typically  $(V+) - 1.2$  V to  $(V+) - 1$  V, in which both pairs are on. This 200-mV transition region can vary up to 200 mV with process variation. Thus, the transition region (both stages on) can range from  $(V+) - 1.4$  V to  $(V+) - 1.2$  V on the low end, up to  $(V+) - 1$  V to  $(V+) - 0.8$  V on the high end. Within this transition region, PSRR, CMRR, offset voltage, offset drift, and THD can be degraded compared to device operation outside this region.

### 7.3.3 Input and ESD Protection

The OPA316 family incorporates internal ESD protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes also provide in-circuit, input overdrive protection, as long as the current is limited to 10 mA as stated in the [Absolute Maximum Ratings](#). Figure 37 shows how a series input resistor can be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and its value must be kept to a minimum in noise-sensitive applications.

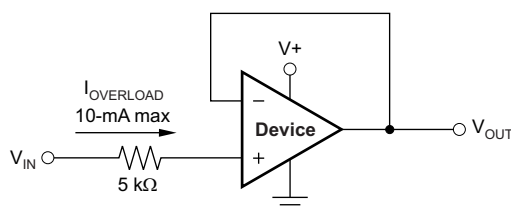


Figure 37. Input Current Protection

### 7.3.4 Common-Mode Rejection Ratio (CMRR)

CMRR for the OPA316 is specified in several ways so the user can select the best match for a given application (see the [Electrical Characteristics](#)). First, the data sheet gives the CMRR of the device in the common-mode range below the transition region [ $V_{CM} < (V+) - 1.4$  V]. This specification is the best indicator of device capability when the application requires use of one of the differential input pairs. Second, the CMRR over the entire common-mode range is specified at  $V_{CM} = -0.2$  V to 5.7 V for  $V_S = 5.5$  V. This last value includes the variations seen (TBD cannot use "seen") through the transition region (see Figure 4).

### 7.3.5 EMI Susceptibility and Input Filtering

Operational amplifiers vary with regard to the susceptibility of the device to electromagnetic interference (EMI). If conducted EMI enters the operational amplifier, the dc offset observed at the amplifier output can shift from its nominal value when EMI is present. This shift is a result of signal rectification associated with the internal semiconductor junctions. Although all operational amplifier pin functions can be affected by EMI, the signal input pins are likely to be the most susceptible. The OPA316 operational amplifier family incorporates an internal input low-pass filter that reduces the amplifier response to EMI. This filter provides both common-mode and differential-mode filtering. The filter is designed for a cutoff frequency of approximately 80 MHz ( $-3$  dB), with a roll-off of 20 dB per decade.

TI developed the ability to accurately measure and quantify the immunity of an operational amplifier over a broad frequency spectrum extending from 10 MHz to 6 GHz. The EMI rejection ratio (EMIRR) metric allows operational amplifiers to be directly compared by the EMI immunity. Figure 35 illustrates the results of this testing on the OPA316. Detailed information can also be found in the application report, *EMI Rejection Ratio of Operational Amplifiers* (SBOA128), available for download from [www.ti.com](http://www.ti.com).

### 7.3.6 Rail-to-Rail Output

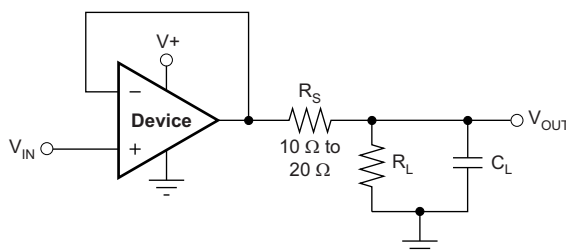
Designed as a low-power, low-noise operational amplifier, the OPA316 delivers a robust output drive capability. A class AB output stage with common-source transistors is used to achieve full rail-to-rail output swing capability. For resistive loads of 10 kΩ, the output swings typically to within 30 mV of either supply rail regardless of the power-supply voltage applied. Different load conditions change the ability of the amplifier to swing close to the rails; refer to the typical characteristic graph *Output Voltage Swing vs Output Current* (Figure 11).

## Feature Description (continued)

### 7.3.7 Capacitive Load and Stability

The OPA316 is designed to be used in applications where driving a capacitive load is required. As with all operational amplifiers, there may be specific instances where the OPA316 can become unstable. The particular operational amplifier circuit configuration, layout, gain, and output loading are some of the factors to consider when establishing whether or not an amplifier is stable in operation. An operational amplifier in the unity-gain (+1 V/V) buffer configuration that drives a capacitive load exhibits a greater tendency to be unstable than an amplifier operated at a higher noise gain. The capacitive load, in conjunction with the operational amplifier output resistance, creates a pole within the feedback loop that degrades the phase margin. The degradation of the phase margin increases as the capacitive loading increases. As a conservative best practice, designing for 25% overshoot (40° phase margin) provides improved stability over process variations. The equivalent series resistance (ESR) of some very-large capacitors ( $C_L$  greater than 1  $\mu$ F) is sufficient to alter the phase characteristics in the feedback loop such that the amplifier remains stable. Increasing the amplifier closed-loop gain allows the amplifier to drive increasingly larger capacitance. This increased capability is evident when observing the overshoot response of the amplifier at higher voltage gains. See the typical characteristic graphs, *Small-Signal Overshoot vs Capacitive Load* (Figure 24,  $G = -1$  V/V) and *Small-Signal Overshoot vs Capacitive Load* (Figure 25,  $G = +1$  V/V).

One technique for increasing the capacitive load drive capability of the amplifier operating in a unity-gain configuration is to insert a small resistor (typically 10  $\Omega$  to 20  $\Omega$ ) in series with the output, as shown in Figure 38. This resistor significantly reduces the overshoot and ringing associated with large capacitive loads. One possible problem with this technique, however, is that a voltage divider is created with the added series resistor and any resistor connected in parallel with the capacitive load. The voltage divider introduces a gain error at the output that reduces the output swing.



**Figure 38. Improving Capacitive Load Drive**

### 7.3.8 Overload Recovery

Overload recovery is defined as the time required for the operational amplifier output to recover from a saturated state to a linear state. The output devices of the operational amplifier enter a saturation region when the output voltage exceeds the rated operating voltage, either because of the high input voltage or the high gain. After the device enters the saturation region, the charge carriers in the output devices require time to return back to the linear state. After the charge carriers return back to the linear state, the device begins to slew at the specified slew rate. Thus, the propagation delay in case of an overload condition is the sum of the overload recovery time and the slew time. The overload recovery time for the OPA316 is approximately 300 ns.

### 7.3.9 DFN Package

The OPA2316 (dual version) uses the DFN style package (also known as SON); this package is a QFN with contacts on only two sides of the package bottom. This leadless package maximizes printed circuit board (PCB) space and offers enhanced thermal and electrical characteristics through an exposed pad. One of the primary advantages of the DFN package is its low, 0.9-mm height. DFN packages are physically small, have a smaller routing area, improved thermal performance, reduced electrical parasitics, and use a pinout scheme that is consistent with other commonly-used packages (such as SOIC and MSOP). Additionally, the absence of external leads eliminates bent-lead issues.

The DFN package can be easily mounted using standard PCB assembly techniques. See application notes, *QFN/SON PCB Attachment* (SLUA271), and *Quad Flatpack No-Lead Logic Packages* (SCBA017), both available for download from [www.ti.com](http://www.ti.com).

## Feature Description (continued)

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### NOTE

Connect the exposed lead frame die pad on the bottom of the DFN package to the most negative potential (V–).

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## 7.4 Device Functional Modes

The OPA316, OPA2316, and OPA4316 are powered on when the supply is connected. The devices can be operated as a single-supply operational amplifier or a dual-supply amplifier, depending on the application.

The OPA2316S has a SHDN (enable) pin function referenced to the negative supply voltage of the operational amplifier. A logic level high enables the operational amplifier. A valid logic high is defined as voltage  $[(V+) - 0.1 \text{ V}]$ , up to  $(V+)$ , applied to the SHDN pin. A valid logic low is defined as  $[(V-) + 0.1 \text{ V}]$ , down to  $(V-)$ , applied to the enable pin. The maximum allowed voltage applied to SHDN is 5.5 V with respect to the negative supply, independent of the positive supply voltage. Connect this pin to a valid high or a low voltage or driven, but not left as an open circuit.

The logic input is a high-impedance CMOS input. Both inputs are independently controlled. For battery-operated applications, this feature can be used to greatly reduce the average current and extend battery life.

## 8 Application and Implementation

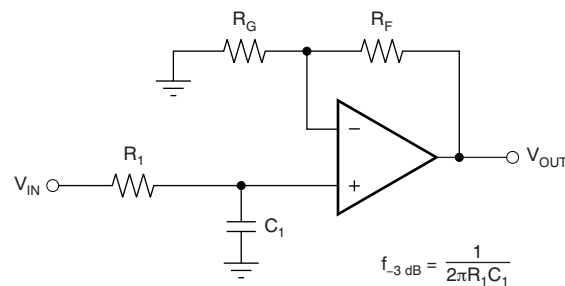
### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

#### 8.1.1 General Configurations

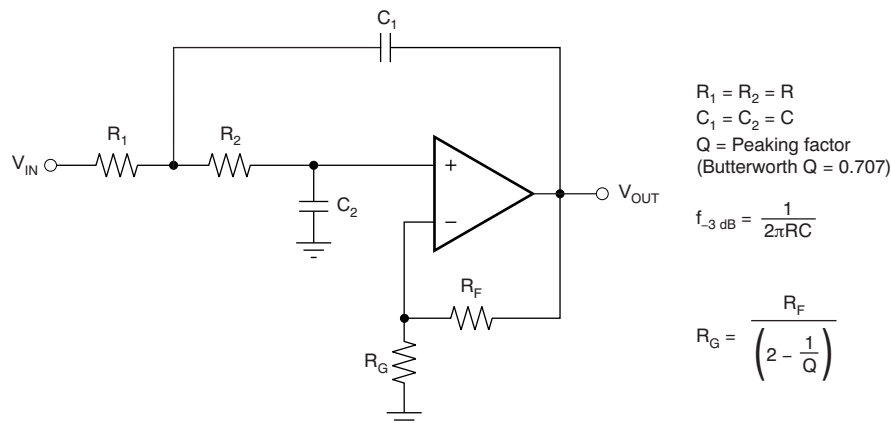
When receiving low-level signals, the device often requires limiting the bandwidth of the incoming signals into the system. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting pin of the amplifier, as [Figure 39](#) shows.



$$\frac{V_{\text{OUT}}}{V_{\text{IN}}} = \left(1 + \frac{R_F}{R_G}\right) \left(\frac{1}{1 + sR_1 C_1}\right)$$

**Figure 39. Single-Pole Low-Pass Filter**

If even more attenuation is needed, the device requires a multiple-pole filter. The Sallen-Key filter can be used for this task, as [Figure 40](#) shows. For best results, the amplifier must have a bandwidth that is 8× to 10× the filter frequency bandwidth. Failure to follow this guideline can result in phase shift of the amplifier.



**Figure 40. Two-Pole, Low-Pass, Sallen-Key Filter**

## 8.2 Typical Application

Some applications require differential signals. [Figure 41](#) shows a simple circuit to convert a single-ended input of 0.1 V to 2.4 V into a differential output of  $\pm 2.3$  V on a single 2.7-V supply. The output range is intentionally limited to maximize linearity. The circuit is composed of two amplifiers. One amplifier functions as a buffer and creates a voltage,  $V_{out+}$ . The second amplifier inverts the input and adds a reference voltage to generate  $V_{out-}$ . Both  $V_{out+}$  and  $V_{out-}$  range from 0.1 V to 2.4 V. The difference,  $V_{diff}$ , is the difference between  $V_{out+}$  and  $V_{out-}$ . This (TBD this what?) makes the differential output voltage range 2.3 V.

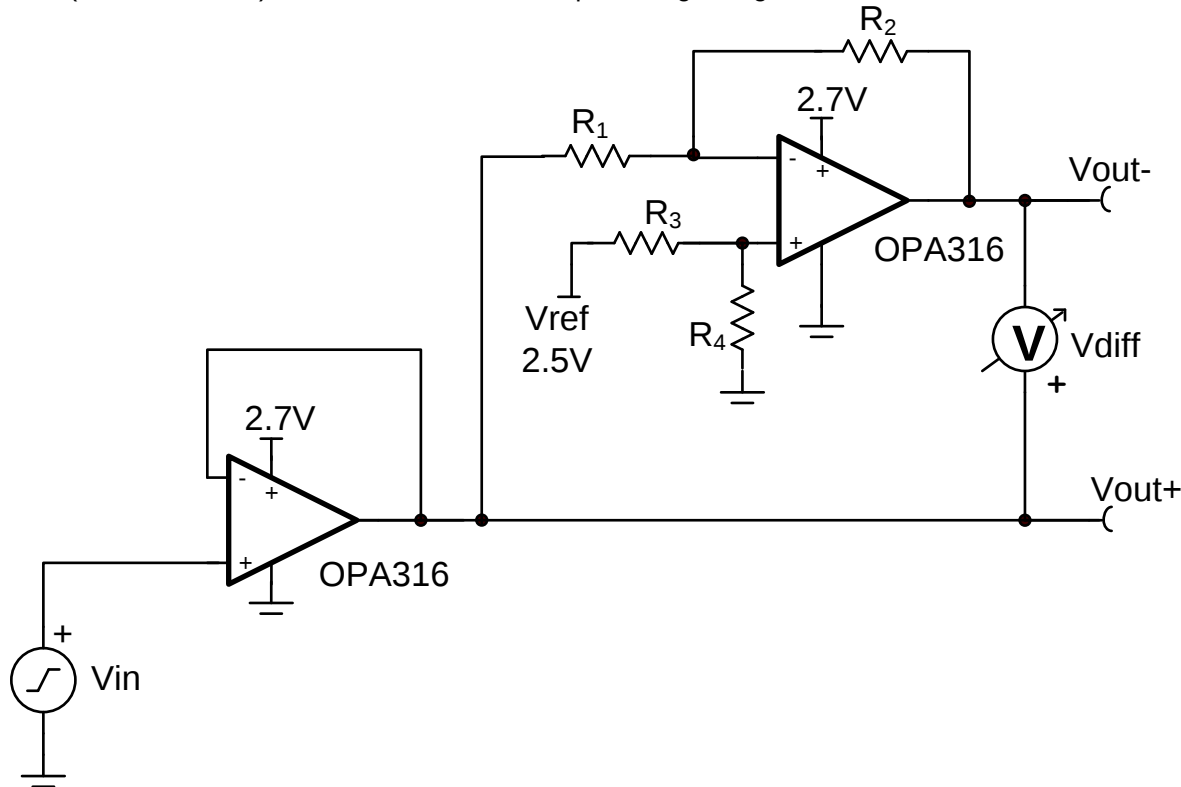


Figure 41. Schematic for a Single-Ended Input to Differential Output Conversion

### 8.2.1 Design Requirements

The design requirements are as follows:

- Supply voltage: 2.7 V
- Reference voltage: 2.5 V
- Input: 0.1 V to 2.4 V
- Output differential:  $\pm 2.3$  V
- Output common-mode voltage: 1.25 V
- Small-signal bandwidth: 5 MHz

### 8.2.2 Detailed Design Procedure

The circuit in [Figure 41](#) takes a single-ended input signal,  $V_{in}$ , and generates two output signals,  $V_{out+}$  and  $V_{out-}$  using two amplifiers and a reference voltage,  $V_{ref}$ .  $V_{out+}$  is the output of the first amplifier and is a buffered version of the input signal,  $V_{in}$  (as shown in [Equation 1](#)).  $V_{out-}$  is the output of the second amplifier which uses  $V_{ref}$  to add an offset voltage to  $V_{in}$  and feedback to add inverting gain. The transfer function for  $V_{out-}$  is given in [Equation 2](#).

$$V_{out+} = V_{in} \quad (1)$$

$$V_{out-} = V_{ref} \times \left( \frac{R_4}{R_3 + R_4} \right) \times \left( 1 + \frac{R_2}{R_1} \right) - V_{in} \times \frac{R_2}{R_1} \quad (2)$$

## Typical Application (continued)

The differential output signal,  $V_{diff}$ , is the difference between the two single-ended output signals,  $V_{out+}$  and  $V_{out-}$ . Equation 3 shows the transfer function for  $V_{diff}$ . By applying the conditions that  $R_1 = R_2$  and  $R_3 = R_4$ , the transfer function is simplified into Equation 6. Using this configuration, the maximum input signal is equal to the reference voltage and the maximum output of each amplifier is equal to  $V_{ref}$ . The differential output range is  $2 \times V_{ref}$ . Furthermore, the common-mode voltage is one half of  $V_{ref}$  (see Equation 7). TBD Equation 4 and Equation 5 need text references

$$V_{diff} = V_{out+} - V_{out-} = V_{in} \times \left(1 + \frac{R_2}{R_1}\right) - V_{ref} \times \left(\frac{R_4}{R_3 + R_4}\right) \times \left(1 + \frac{R_2}{R_1}\right) \quad (3)$$

$$V_{out+} = V_{in} \quad (4)$$

$$V_{out-} = V_{ref} - V_{in} \quad (5)$$

$$V_{diff} = 2 \times V_{in} - V_{ref} \quad (6)$$

$$V_{cm} = \left(\frac{V_{out+} + V_{out-}}{2}\right) = \frac{1}{2} V_{ref} \quad (7)$$

### 8.2.2.1 Amplifier Selection

Linearity over the input range is key for good dc accuracy. The common-mode input range and output swing limitations determine the linearity. In general, an amplifier with rail-to-rail input and output swing is required. Bandwidth is a key concern for this design, so the OPA316 is selected because its bandwidth is greater than the target of 5 MHz. The bandwidth and power ratio makes this device power efficient and the low offset and drift ensure good accuracy for moderate precision applications.

### 8.2.2.2 Passive Component Selection

Because the transfer function of  $V_{out-}$  is heavily reliant on resistors ( $R_1$ ,  $R_2$ ,  $R_3$ , and  $R_4$ ), use resistors with low tolerances to maximize performance and minimize error. This design uses resistors with resistance values of 49.9 k $\Omega$  and tolerances of 0.1%. However, if the noise of the system is a key parameter, smaller resistance values (6 k $\Omega$  or lower) can be selected to keep the overall system noise low. This (TBD this what?) ensures that the noise from the resistors is lower than the amplifier noise.

## Typical Application (continued)

### 8.2.3 Application Curves

The measured transfer functions in [Figure 42](#), [Figure 43](#), and [Figure 44](#) are generated by sweeping the input voltage from 0.1 V to 2.4 V. The full input range is actually 0 V to 2.5 V, but is restricted by 0.1 V to maintain optimal linearity. For more details on this design and other alternative devices that can be used in place of the OPA316, refer to the Precision Design, *Single-Ended Input to Differential Output Conversion Circuit Reference Design (TIPD131)*.

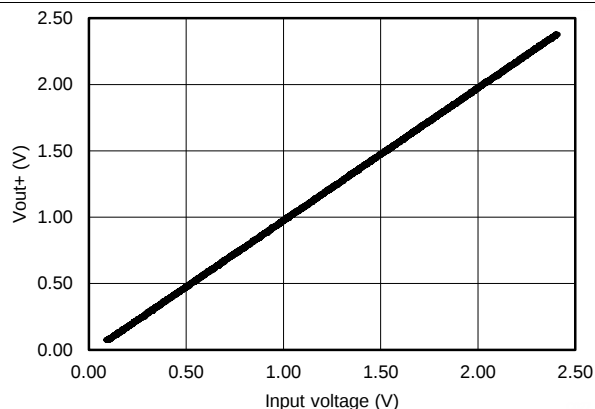


Figure 42. Vout+ vs Input Voltage

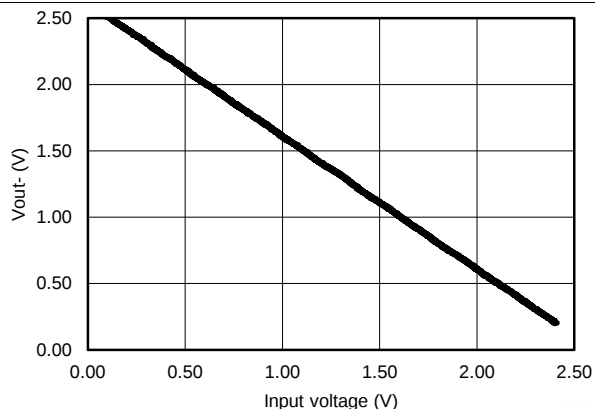


Figure 43. Vout- vs Input Voltage

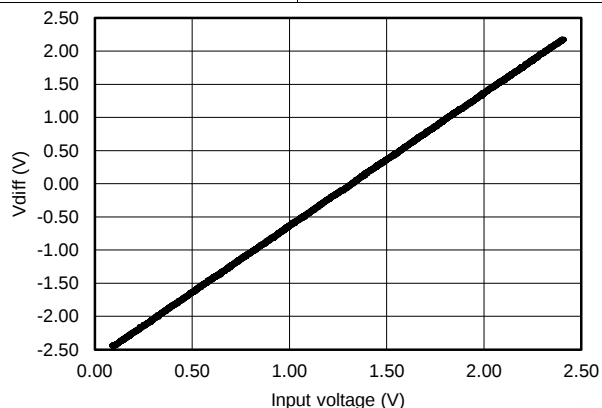


Figure 44. Vdiff vs Input Voltage

## 9 Power Supply Recommendations

The OPA316 is specified for operation from 1.8 V to 5.5 V ( $\pm 0.9$  V to  $\pm 2.75$  V); many specifications apply from  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The [Typical Characteristics](#) presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

### CAUTION

Supply voltages larger than 7 V can permanently damage the device (see the [Absolute Maximum Ratings](#)).

Place 0.1- $\mu\text{F}$  bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, refer to the [Layout Guidelines](#) section.

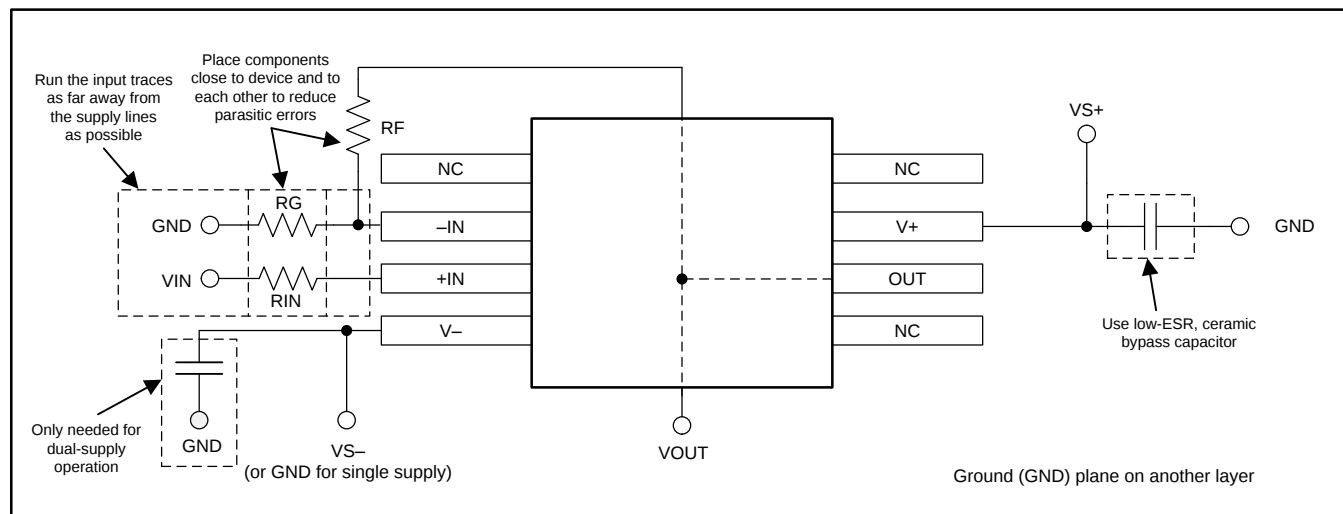
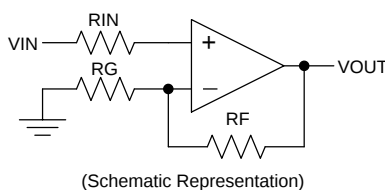
## 10 Layout

### 10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1- $\mu$ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, refer to *Circuit Board Layout Techniques*, [SLOA089](#).
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better than crossing in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in [Layout Example](#).
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

### 10.2 Layout Example



**Figure 45. Operational Amplifier Board Layout for Noninverting Configuration**

## 11 Device and Documentation Support

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

OPAx313 Data Sheet, [SBOS649](#)

OPAx314 Data Sheet, [SBOS563](#)

*EMI Rejection Ratio of Operational Amplifiers*, [SBOA128](#)

*QFN/SON PCB Attachment*, [SLUA271](#)

*Quad Flatpack No-Lead Logic Packages*, [SCBA017](#)

*Single-Ended Input to Differential Output Conversion Circuit Reference Design*, [TIPD131](#)

*Circuit Board Layout Techniques*, [SLOA089](#)

### 11.2 Related Links

The following table lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 2. Related Links**

| PARTS    | PRODUCT FOLDER             | SAMPLE & BUY               | TECHNICAL DOCUMENTS        | TOOLS & SOFTWARE           | SUPPORT & COMMUNITY        |
|----------|----------------------------|----------------------------|----------------------------|----------------------------|----------------------------|
| OPA316   | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| OPA2316  | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| OPA2316S | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |
| OPA4316  | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> | <a href="#">Click here</a> |

### 11.3 Trademarks

All trademarks are the property of their respective owners.

### 11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| OPA2316ID        | ACTIVE        | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | O2316                   | <a href="#">Samples</a> |
| OPA2316IDGK      | ACTIVE        | VSSOP        | DGK                | 8    | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG             | Level-2-260C-1 YEAR  | -40 to 125   | OVMQ                    | <a href="#">Samples</a> |
| OPA2316IDGKR     | ACTIVE        | VSSOP        | DGK                | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG             | Level-2-260C-1 YEAR  | -40 to 125   | OVMQ                    | <a href="#">Samples</a> |
| OPA2316IDR       | ACTIVE        | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | O2316                   | <a href="#">Samples</a> |
| OPA2316IDRGR     | ACTIVE        | SON          | DRG                | 8    | 3000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | SMD                     | <a href="#">Samples</a> |
| OPA2316IDRGT     | ACTIVE        | SON          | DRG                | 8    | 250            | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | SMD                     | <a href="#">Samples</a> |
| OPA2316SIDGS     | ACTIVE        | VSSOP        | DGS                | 10   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG             | Level-2-260C-1 YEAR  | -40 to 125   | SMG                     | <a href="#">Samples</a> |
| OPA2316SIDGSR    | ACTIVE        | VSSOP        | DGS                | 10   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAUAG             | Level-2-260C-1 YEAR  | -40 to 125   | SMG                     | <a href="#">Samples</a> |
| OPA316IDBVR      | ACTIVE        | SOT-23       | DBV                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | SLE                     | <a href="#">Samples</a> |
| OPA316IDBVT      | ACTIVE        | SOT-23       | DBV                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | SLE                     | <a href="#">Samples</a> |
| OPA316IDCKR      | ACTIVE        | SC70         | DCK                | 5    | 3000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | SLD                     | <a href="#">Samples</a> |
| OPA316IDCKT      | ACTIVE        | SC70         | DCK                | 5    | 250            | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 125   | SLD                     | <a href="#">Samples</a> |
| OPA4316IPW       | ACTIVE        | TSSOP        | PW                 | 14   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | OPA4316                 | <a href="#">Samples</a> |
| OPA4316IPWR      | ACTIVE        | TSSOP        | PW                 | 14   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-2-260C-1 YEAR  | -40 to 125   | OPA4316                 | <a href="#">Samples</a> |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| OPA2316IDGKR  | VSSOP        | DGK             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| OPA2316IDR    | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| OPA2316IDRGR  | SON          | DRG             | 8    | 3000 | 330.0              | 12.4               | 3.3     | 3.3     | 1.1     | 8.0     | 12.0   | Q2            |
| OPA2316IDRGT  | SON          | DRG             | 8    | 250  | 180.0              | 12.4               | 3.3     | 3.3     | 1.1     | 8.0     | 12.0   | Q2            |
| OPA2316SIDGSR | VSSOP        | DGS             | 10   | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| OPA316IDBVR   | SOT-23       | DBV             | 5    | 3000 | 178.0              | 9.0                | 3.3     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| OPA316IDBVT   | SOT-23       | DBV             | 5    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| OPA316IDCKR   | SC70         | DCK             | 5    | 3000 | 178.0              | 9.0                | 2.4     | 2.5     | 1.2     | 4.0     | 8.0    | Q3            |
| OPA316IDCKT   | SC70         | DCK             | 5    | 250  | 178.0              | 9.0                | 2.4     | 2.5     | 1.2     | 4.0     | 8.0    | Q3            |
| OPA4316IPWR   | TSSOP        | PW              | 14   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS

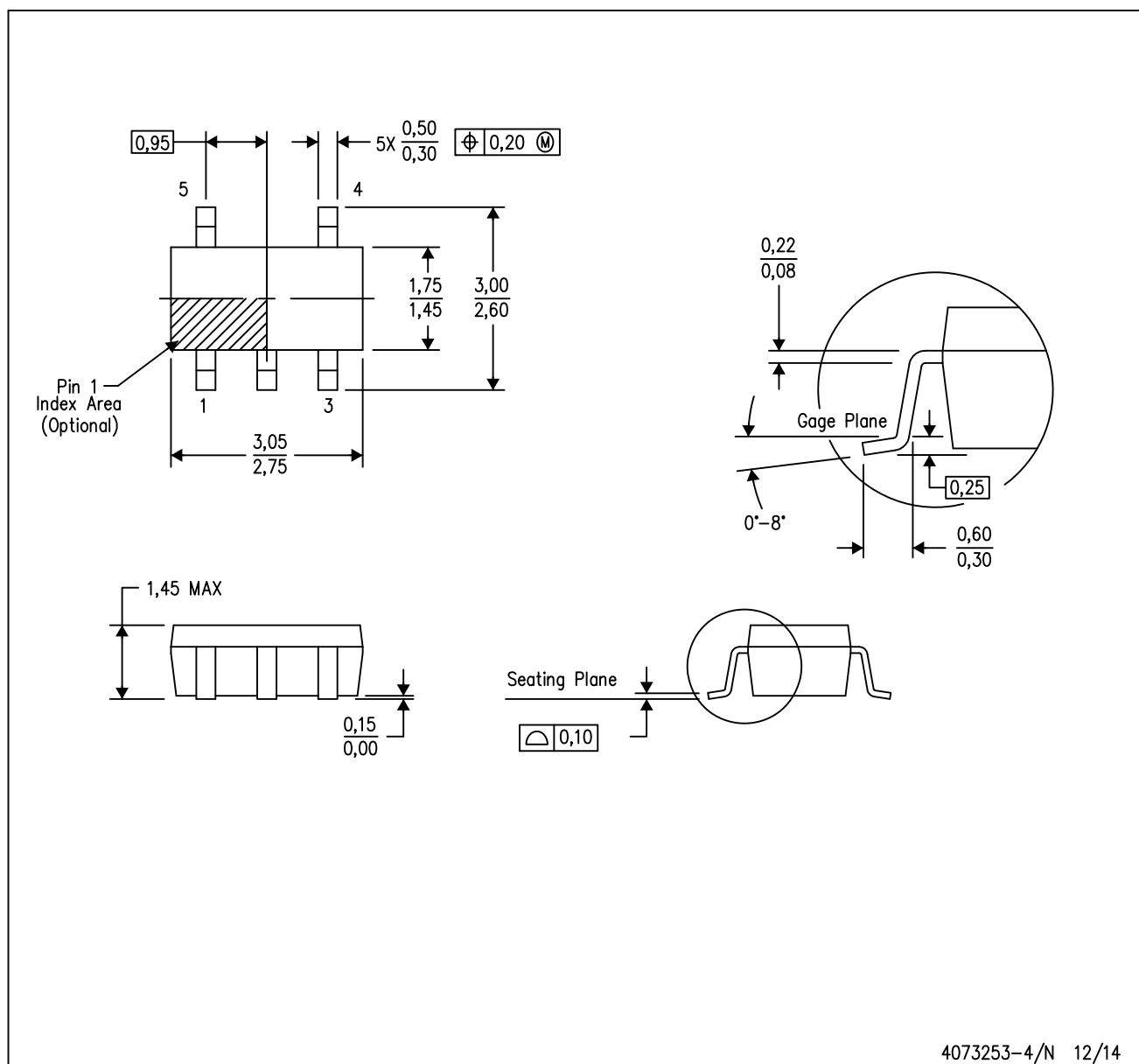


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| OPA2316IDGKR  | VSSOP        | DGK             | 8    | 2500 | 366.0       | 364.0      | 50.0        |
| OPA2316IDR    | SOIC         | D               | 8    | 2500 | 533.4       | 367.0      | 36.0        |
| OPA2316IDRGR  | SON          | DRG             | 8    | 3000 | 367.0       | 367.0      | 35.0        |
| OPA2316IDRGT  | SON          | DRG             | 8    | 250  | 210.0       | 185.0      | 35.0        |
| OPA2316SIDGSR | VSSOP        | DGS             | 10   | 2500 | 366.0       | 364.0      | 50.0        |
| OPA316IDBVR   | SOT-23       | DBV             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| OPA316IDBVT   | SOT-23       | DBV             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| OPA316IDCKR   | SC70         | DCK             | 5    | 3000 | 180.0       | 180.0      | 18.0        |
| OPA316IDCKT   | SC70         | DCK             | 5    | 250  | 180.0       | 180.0      | 18.0        |
| OPA4316IPWR   | TSSOP        | PW              | 14   | 2000 | 367.0       | 367.0      | 35.0        |

DBV (R-PDSO-G5)

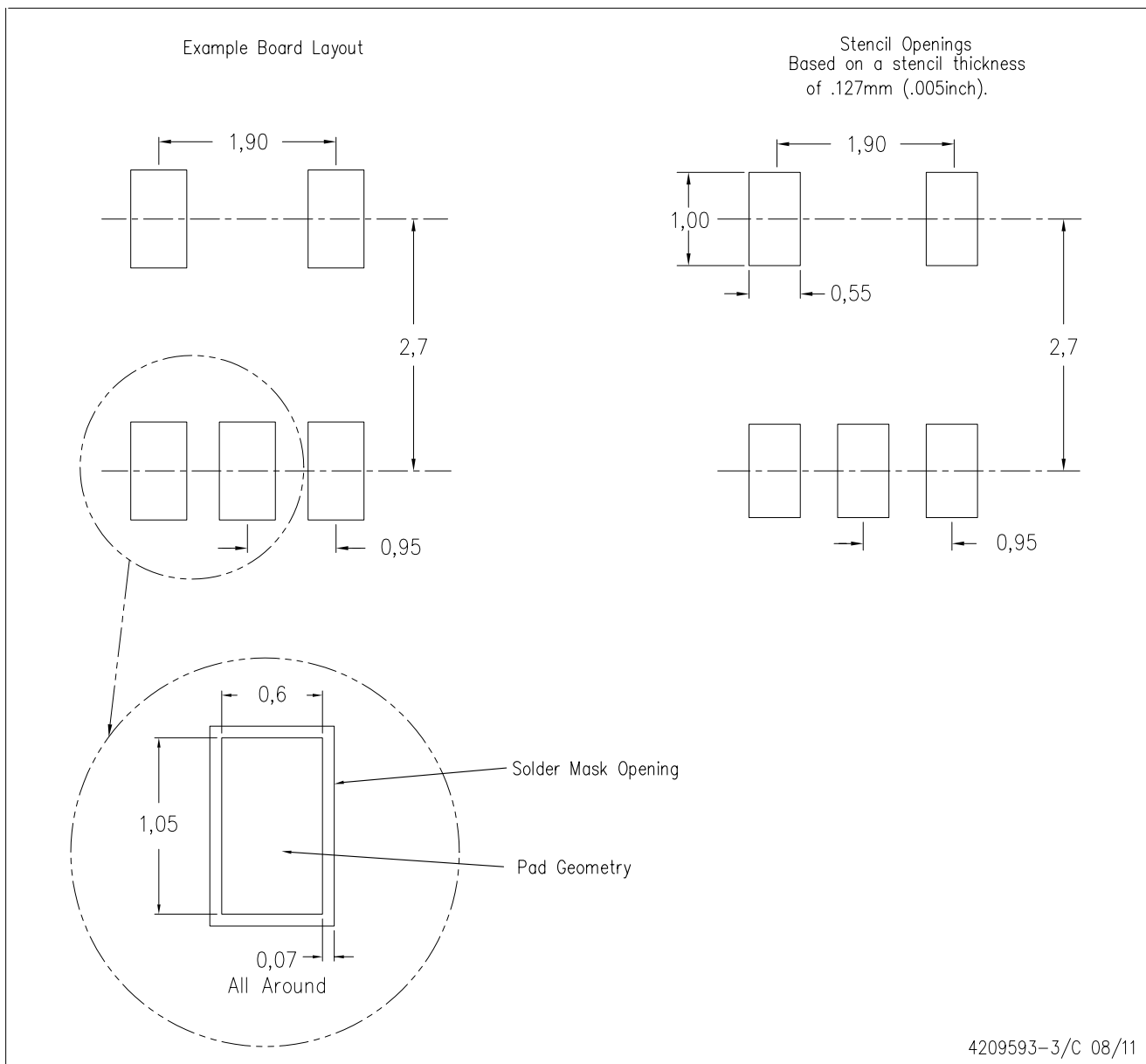
PLASTIC SMALL-OUTLINE PACKAGE



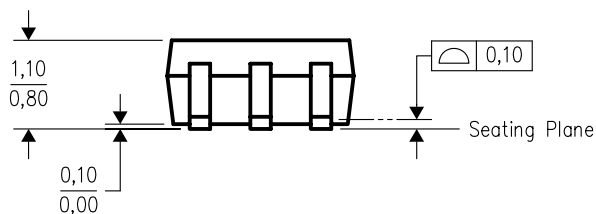
- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.

DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE

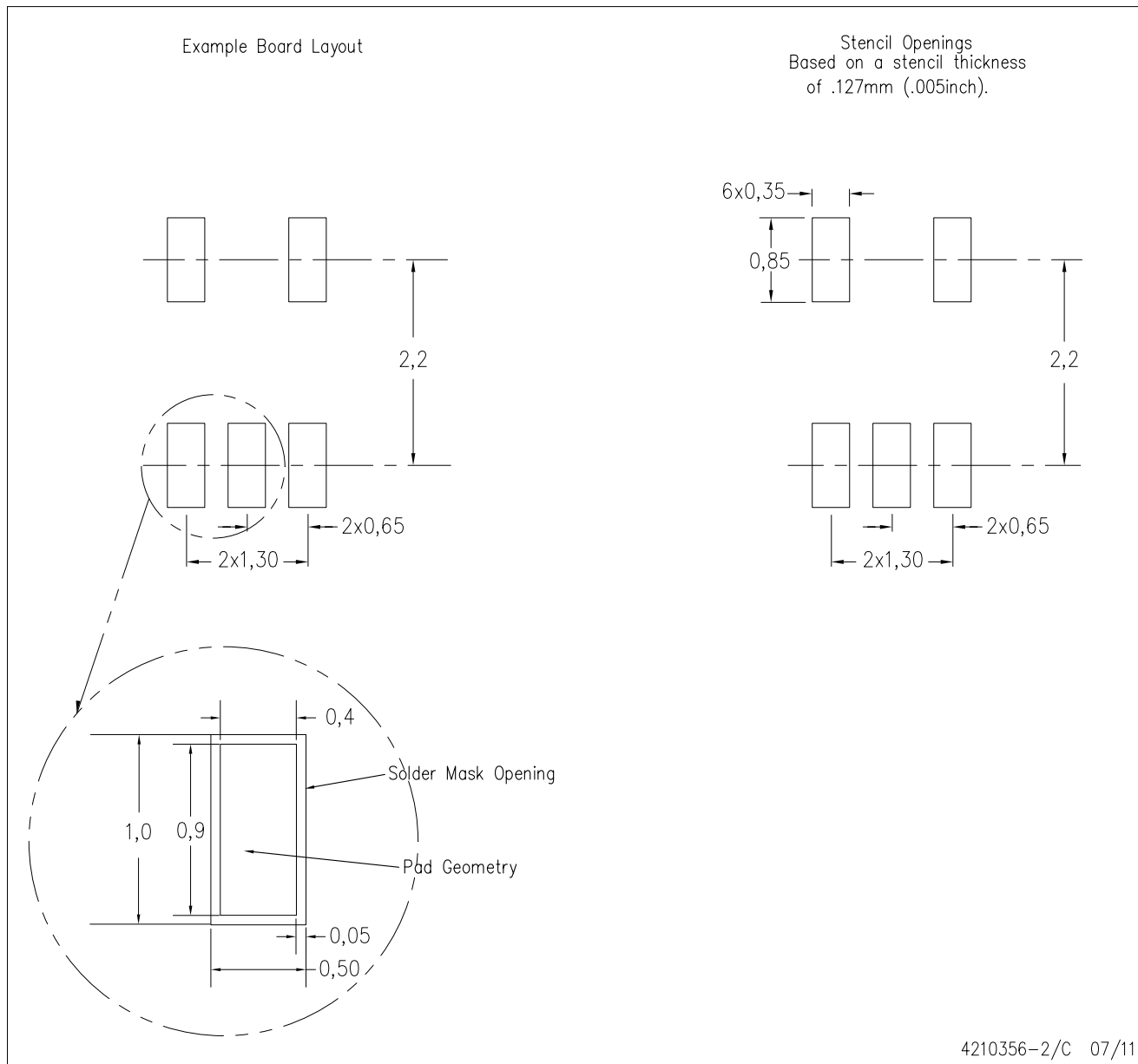


- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



## NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

DGK (S-PDSO-G8)

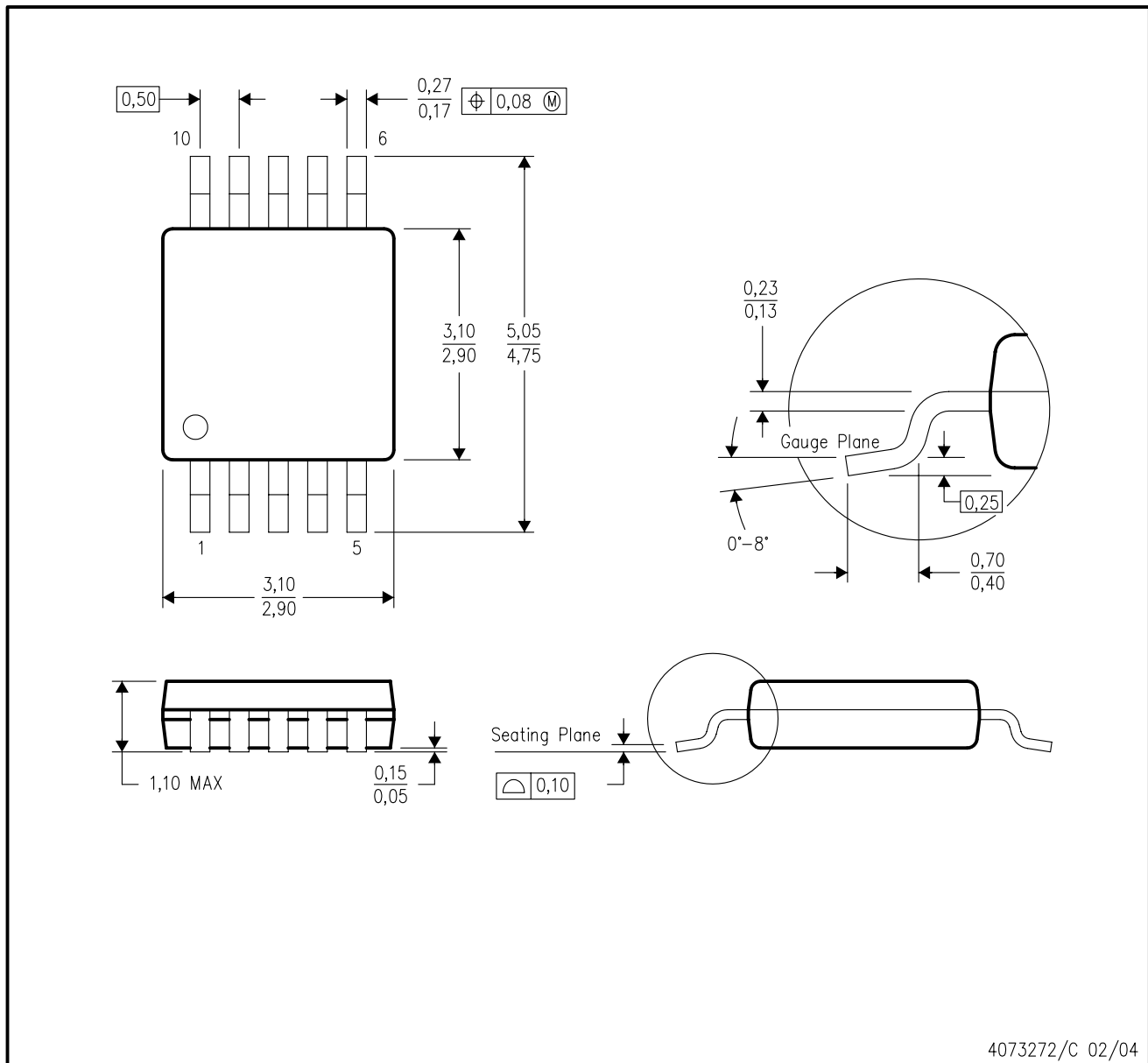
PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

## DGS (S-PDSO-G10)

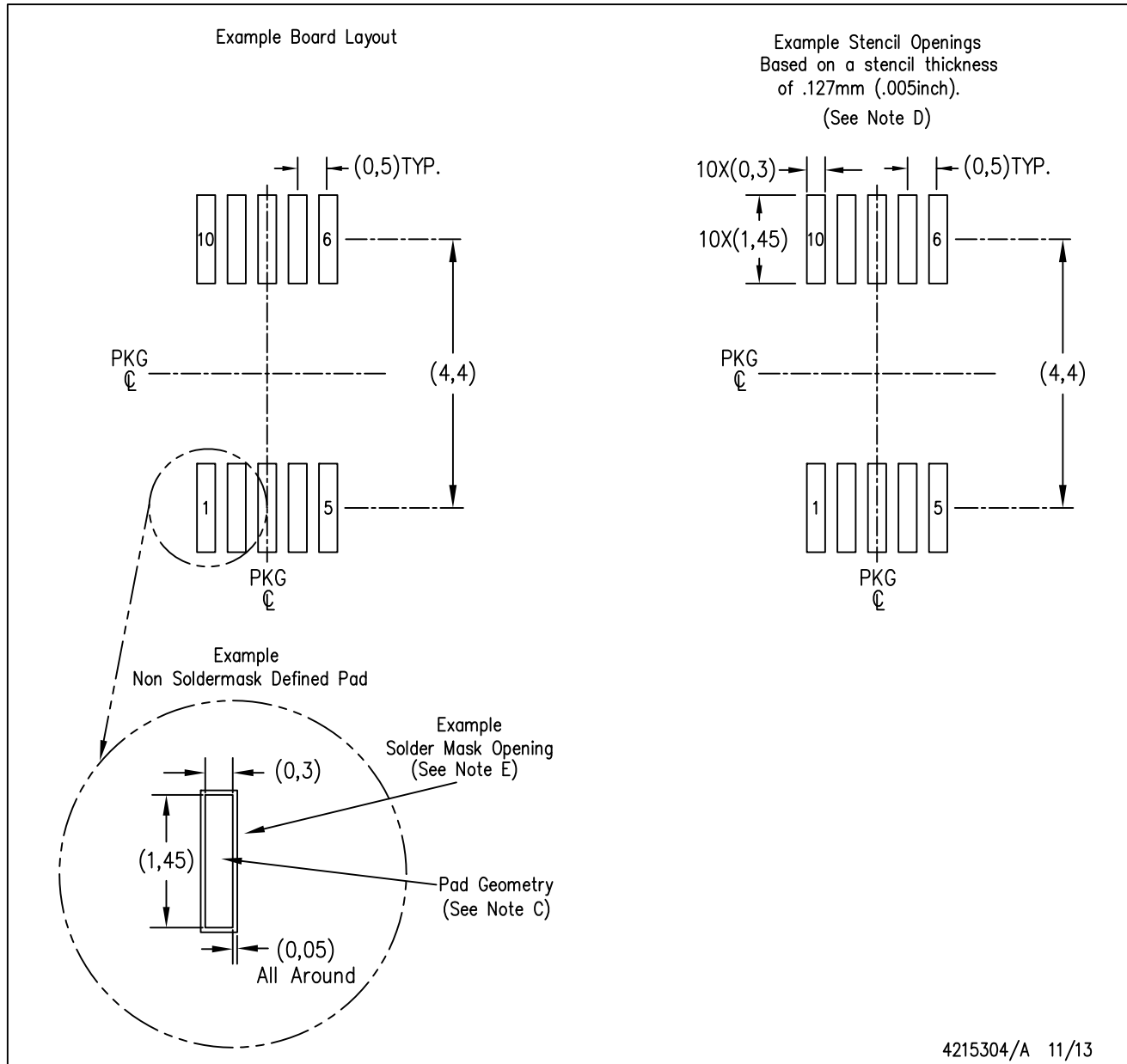
## PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion.
  - D. Falls within JEDEC MO-187 variation BA.

DGS (S-PDSO-G10)

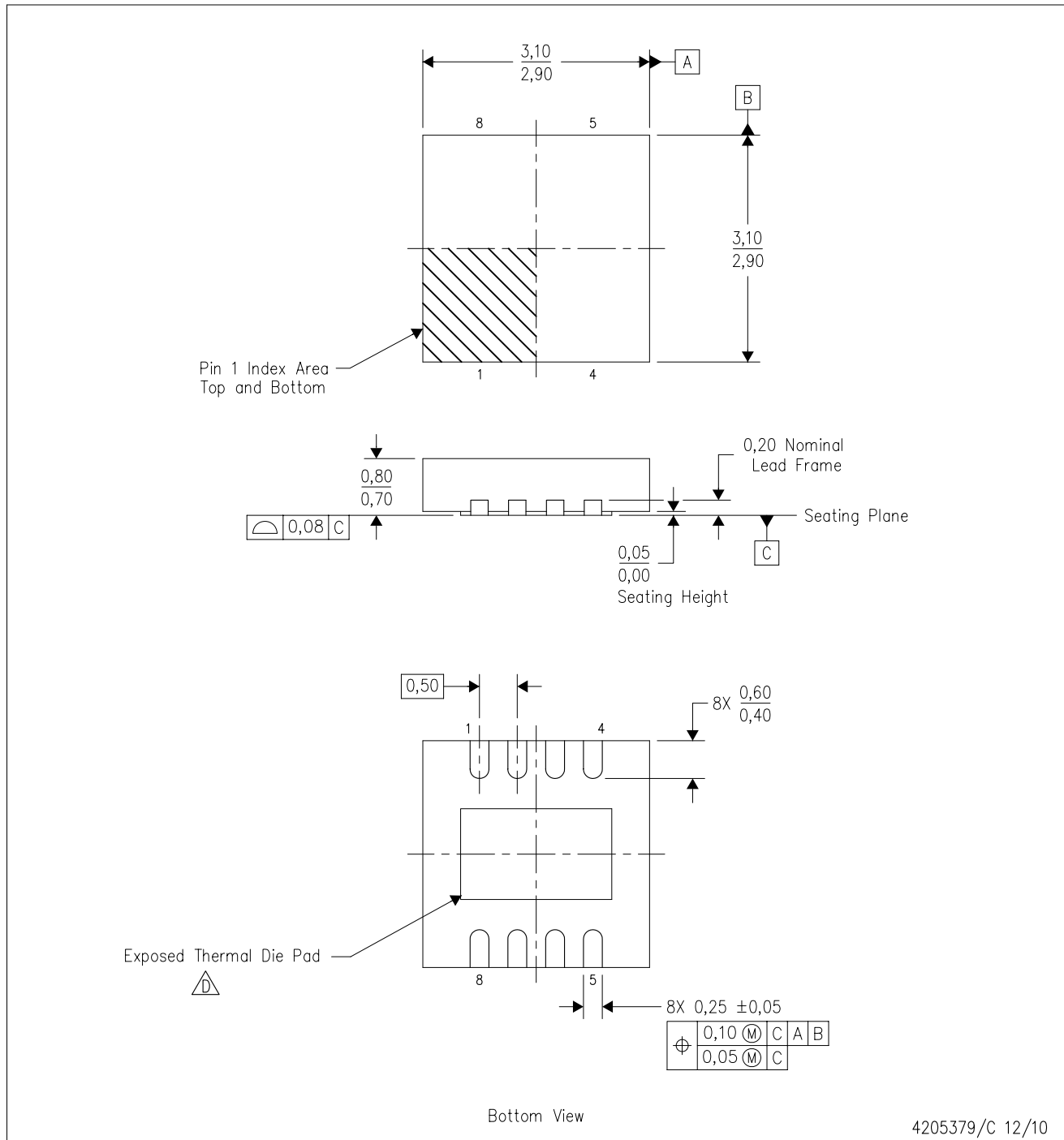
PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DRG (S-PWSON-N8)

PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. SON (Small Outline No-Lead) package configuration.
  - D. The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
  - E. JEDEC MO-229 package registration pending.

DRG (S-PWSON-N8)

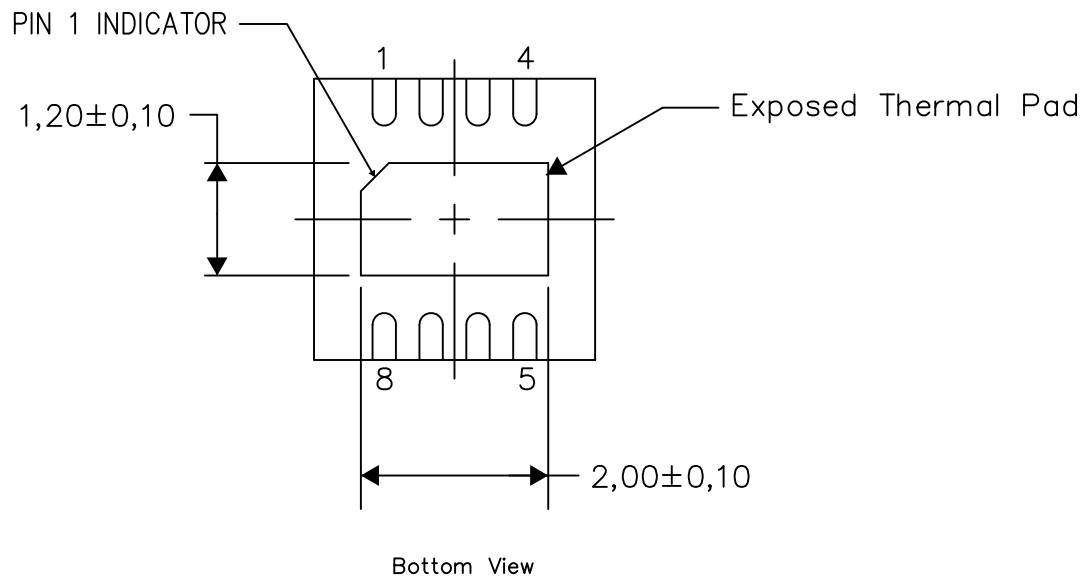
PLASTIC SMALL OUTLINE NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



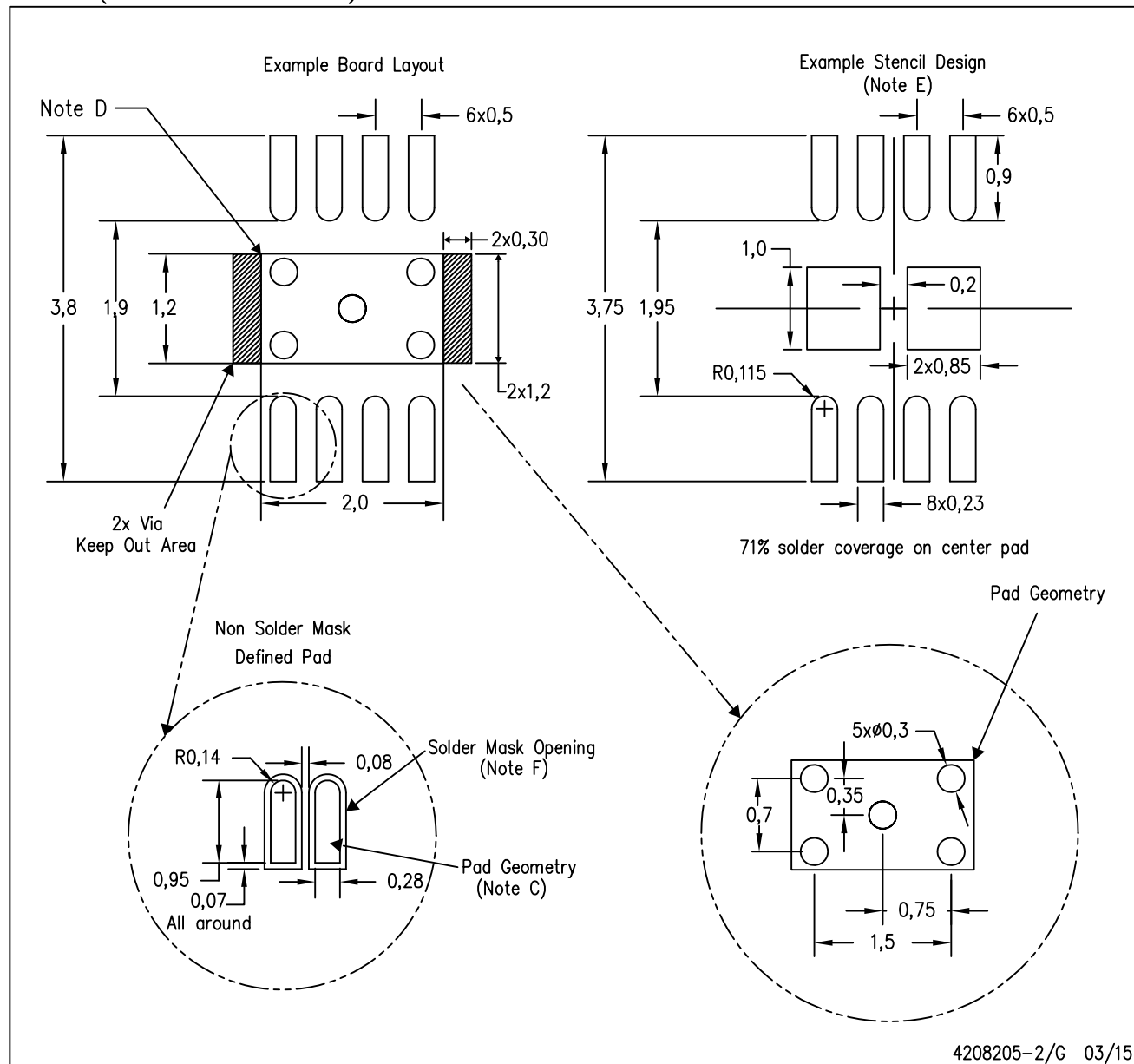
Exposed Thermal Pad Dimensions

4206881-2/1 03/15

NOTE: All linear dimensions are in millimeters

DRG (S-PWSON-N8)

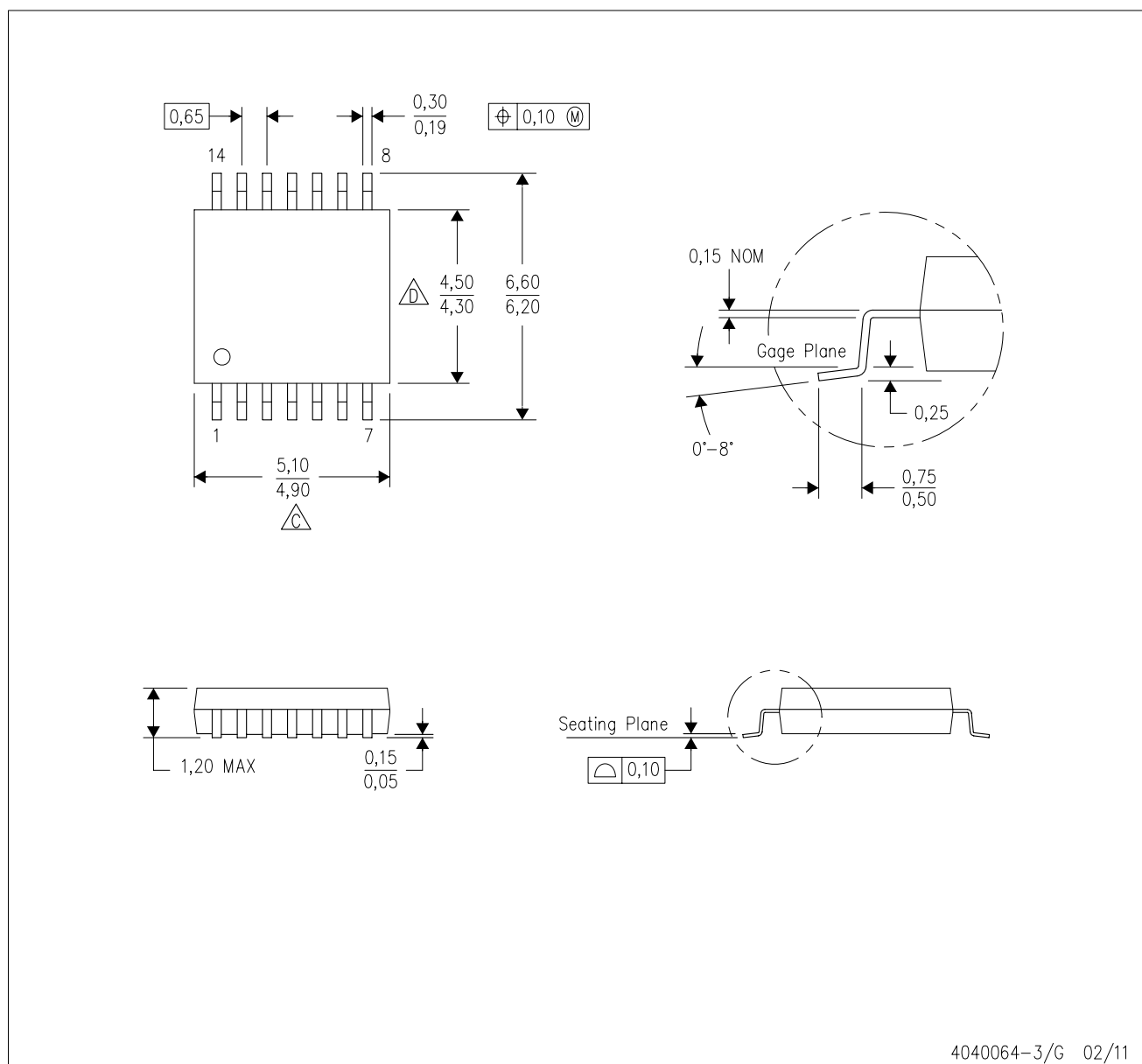
PLASTIC SMALL OUTLINE NO-LEAD



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-SM-782 is recommended for alternate designs.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

PW (R-PDSO-G14)

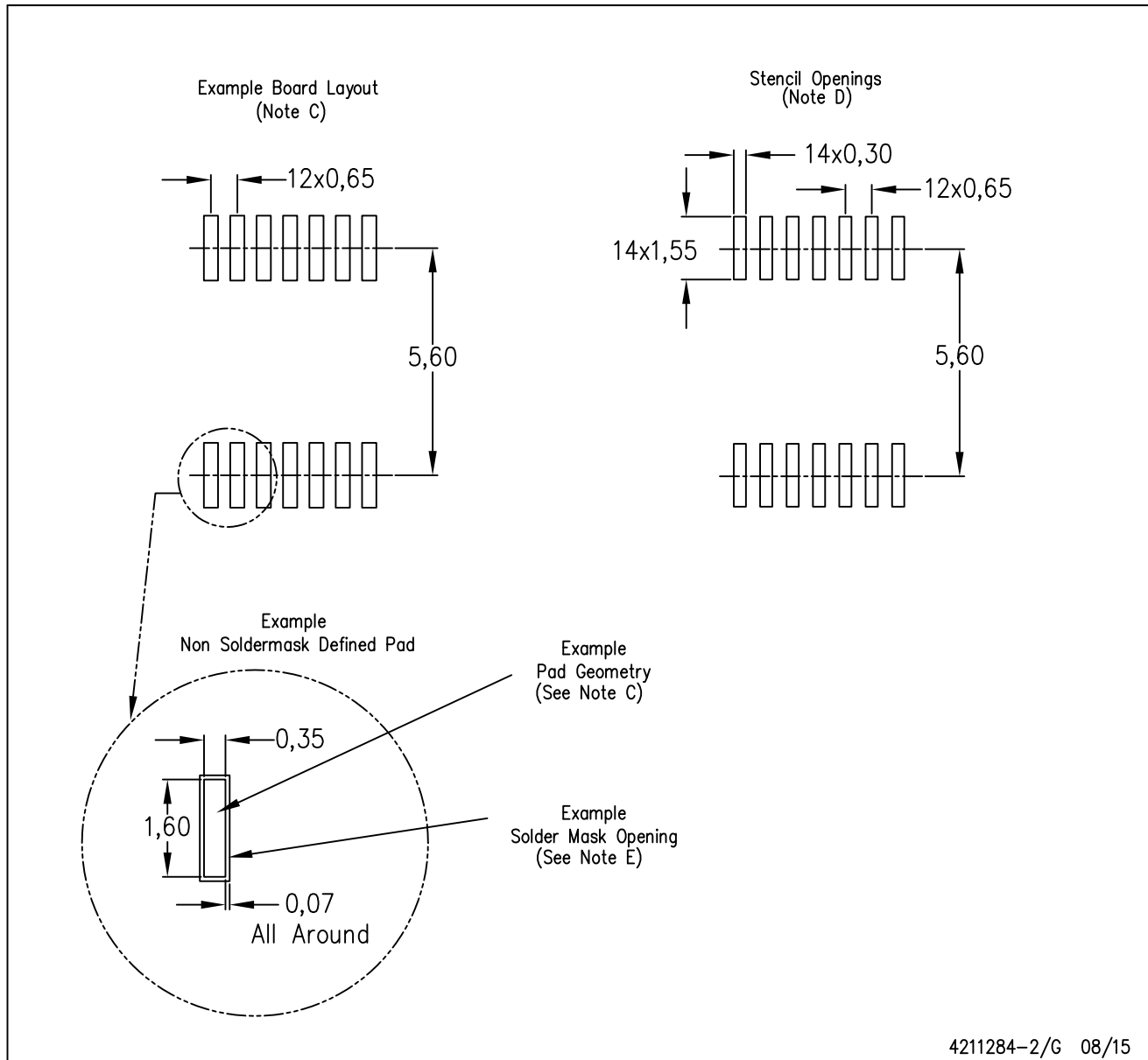
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

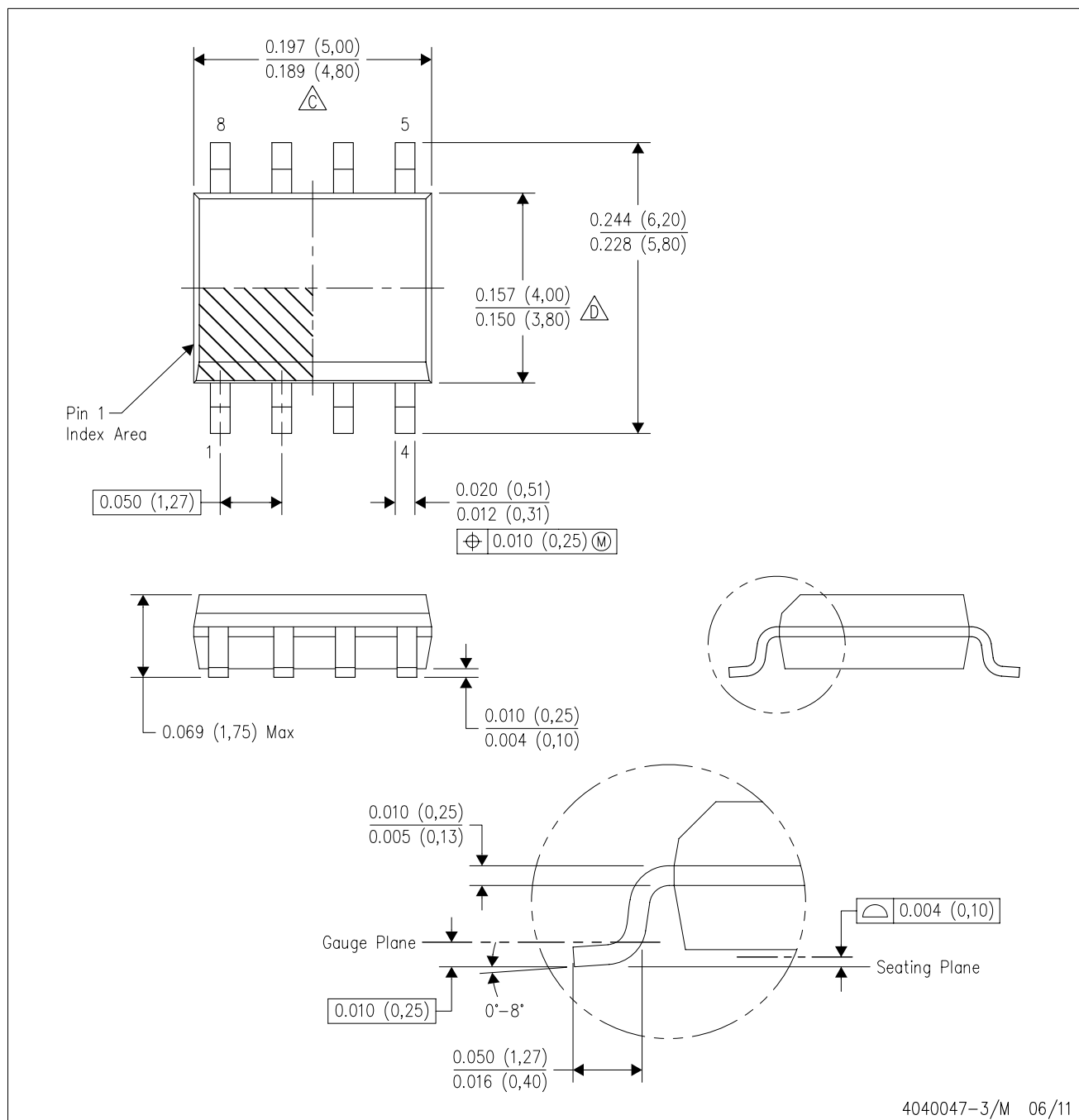
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G8)

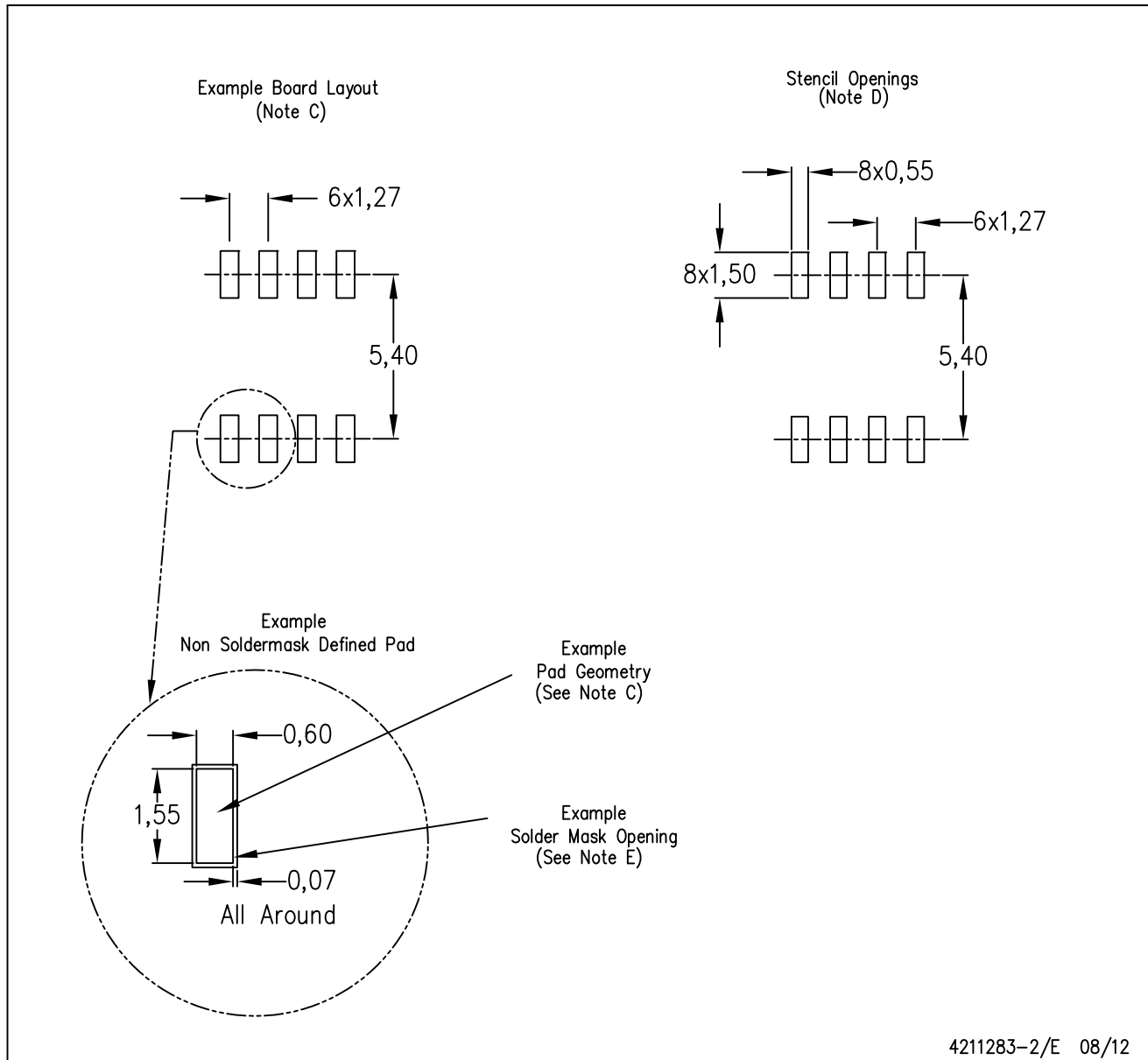
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - $\triangle D$  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



4211283-2/E 08/12

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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| Computers and Peripherals     | <a href="http://www.ti.com/computers">www.ti.com/computers</a>                           |
| Consumer Electronics          | <a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>                   |
| Energy and Lighting           | <a href="http://www.ti.com/energy">www.ti.com/energy</a>                                 |
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| Security                      | <a href="http://www.ti.com/security">www.ti.com/security</a>                             |
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